

带有集成时钟恢复器的 LMH1297 12G UHD-SDI 双向 I/O

1 特性

- 带有集成时钟恢复器的用户可配置型自适应电缆均衡器或电缆驱动器
- 支持 ST-2082-1 (12G)、ST-2081-1 (6G)、ST-424 (3G)、ST-292 (HD) 和 ST-259 (SD)
- 兼容 DVB-ASI 和 AES10 (MADI)
- 集成时钟恢复器锁定为 11.88Gbps、5.94Gbps、2.97Gbps、1.485Gbps 或 1.001 分频子速率和 270Mbps 的 SMPTE 速率
- 片上 75Ω 终端和回损补偿网络
- EQ (均衡器) 模式：
 - 带有集成时钟恢复器的自适应电缆均衡器
 - 具有去加重功能的 100Ω 输出驱动器
 - 时钟恢复型 75Ω 环通输出
 - EQ 模式电缆传输距离 (Belden 1694A, 禁用 SDI_OUT)：
 - 11.88Gbps 时为 75m
 - 5.94Gbps 时为 120m
 - 2.97Gbps 时为 200m
 - 1.485Gbps 时为 300m
 - 270Mbps 时为 600m
- 电缆驱动器 (CD) 模式：
 - 带有集成时钟恢复器的双路差分输出电缆驱动器
 - 自适应 PCB 输入均衡器
 - 时钟恢复型 100Ω 环回输出
- 75Ω 输出端的自动预加重和转换率控制
- 75Ω 和 100Ω 输出端的极性反转
- 没有输入信号时自动进入省电工作模式
 - 功耗：25 mW (典型值)
- 通过 ENABLE 引脚进行断电控制
- 2.5V 单电源
 - EQ 模式功率耗散：275 mW (典型值)
 - CD 模式功率耗散：305 mW (典型值)
- 可通过引脚、SPI 或 SMBus 接口进行编程
- 工作温度范围：-40°C 至 +85°C
- 5mm × 5 mm、32 引脚 QFN 封装

2 应用

- [SMPTE 兼容串行数字接口](#)
- [UHDTV/4K/8K/HDTV/SDTV 视频](#)
- [IP 媒体网关](#)
- [数字视频处理和编辑](#)

3 说明

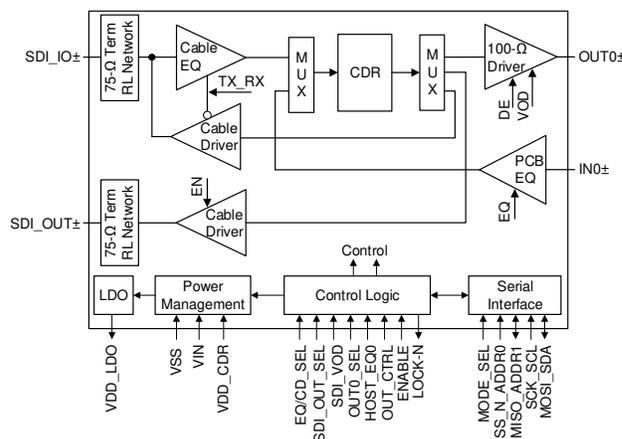
LMH1297 是带有集成时钟恢复器的 12G UHD-SDI 75Ω 双向 I/O。此器件可以在输入模式下配置为自适应电缆均衡器，也可以在输出模式下配置为双电缆驱动器，允许系统设计人员灵活地将单个 BNC 用作输入或输出端口，从而简化 UHD 视频硬件设计。集成的时钟恢复器在两种模式下均可锁定到所有支持的高达 11.88Gbps 的 SMPTE 数据速率。此双向 I/O 具有片上 75Ω 终端和回损补偿网络，满足严格的 SMPTE 回损要求。

额外的 75Ω 驱动器输出可让 LMH1297 支持各种系统功能。在 EQ (均衡器) 模式下，该第二个 75Ω 驱动器可用作环通输出。在电缆驱动器 (CD) 模式下，该 75Ω 驱动器可用作第二个扇出电缆驱动器。主机侧 100Ω 驱动器也可在 CD 模式下用作环回输出，从而用于监控。

器件信息(1)

器件型号	封装	封装尺寸 (标称值)
LMH1297	QFN (32)	5.00mm × 5.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



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简化版方框图

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

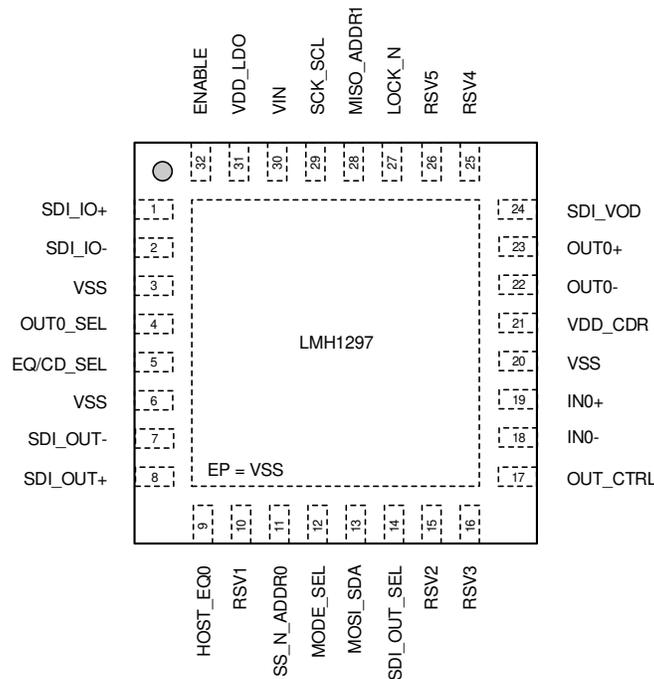
Changes from Revision D (May 2020) to Revision E (July 2022)	Page
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• 在整个数据表中添加了包容性术语.....	1
• Changed CD _{ON_IN0} and CD _{OFF_IN0} Test Condition to "11.88 Gbps PRBS10 pattern".....	8
• Removed 12G/6G from V _{DC_WANDER} Test Condition.....	8
• Added table note to Serial Parallel Interface (SPI) Timing Specifications.....	14
• Updated Line-Side Adaptive Cable Equalizer (SDI_IO+ in EQ mode).....	21
• Updated Line-Side Output Cable Driver (SDI_IO+ in CD mode, SDI_OUT+ in EQ or CD mode).....	23
Changes from Revision C (July 2019) to Revision D (May 2020)	Page
• Changed HBM ESD rating and added pin 27 description	7
Changes from Revision B (September 2017) to Revision C (July 2019)	Page
• 首次公开发布的文档.....	1

5 说明 (续)

片上时钟恢复器可减弱高频抖动并使用纯净的低抖动时钟完全重新生成数据。此时钟恢复器具有内置环路滤波器，且不需要任何输入参考时钟。LMH1297 还有内部眼图张开度监视器和可编程引脚，以便进行 CDR 锁定指示、输入载波检测或硬件中断，从而支持系统诊断和电路板启动。

LMH1297 由 2.5V 单电源供电运行。其采用小尺寸 5mm × 5mm 32 引脚 QFN 封装。

6 Pin Configuration and Functions



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图 6-1. RTV Package 32-Pin QFN (Top View)

表 6-1. Pin Functions

PIN		I/O ⁽¹⁾	DESCRIPTION
NAME	NO.		
HIGH-SPEED DIFFERENTIAL I/OS			
SDI_IO+	1	I/O, Analog	Single-ended complementary inputs or outputs with on-chip 75-Ω termination at SDI_IO+ and SDI_IO-. SDI_IO± include integrated return loss networks designed to meet the SMPTE input and output return loss requirements. Connect SDI_IO+ to a BNC through a 4.7-μF, AC-coupling capacitor. SDI_IO- should be similarly AC-coupled and terminated with an external 4.7-μF capacitor and 75-Ω resistor to GND. EQ mode: SDI_IO+ is the 75-Ω input port of the adaptive cable equalizer for SMPTE video applications. CD mode: SDI_IO+ is the 75-Ω output port of the cable driver for SMPTE video applications.
SDI_IO-	2	I/O, Analog	
SDI_OUT-	7	O, Analog	Single-ended complementary outputs with on-chip 75-Ω termination at SDI_OUT+ and SDI_OUT-. SDI_OUT± include integrated return loss networks designed to meet the SMPTE output return loss requirements. SDI_OUT± is used as a second cable driver. Connect SDI_OUT+ to a BNC through a 4.7-μF, AC-coupling capacitor. SDI_OUT- should be similarly AC-coupled and terminated with an external 4.7-μF capacitor and 75-Ω resistor to GND. EQ mode: SDI_OUT± can be enabled as a loop-through 75-Ω output port. It outputs the reclocked data from the adaptive cable equalizer to form a loop-through output with adaptive cable equalizer, reclocker, and cable driver. CD mode: SDI_OUT± is the second 75-Ω fan-out cable driver.
SDI_OUT+	8	O, Analog	
IN0-	18	I, Analog	Differential inputs from host video processor. On-chip 100-Ω differential termination. Requires external 4.7-μF, AC-coupling capacitors for SMPTE applications.
IN0+	19	I, Analog	
OUT0-	22	O, Analog	Differential outputs to host video processor. On-chip 100-Ω differential termination. Requires external 4.7-μF, AC-coupling capacitors for SMPTE applications.
OUT0+	23	O, Analog	

表 6-1. Pin Functions (continued)

PIN		I/O ⁽¹⁾	DESCRIPTION
NAME	NO.		
CONTROL PINS			
OUT0_SEL	4	I, LVCMOS	OUT0_SEL enables the use of the 100-Ω host-side output driver at OUT0±. See 表 8-3 for details. OUT0_SEL is internally pulled high by default (OUT0 disabled).
EQ/CD_SEL	5	I, LVCMOS	EQ/CD_SEL selects the signal direction of the LMH1297 bidirectional I/O. It configures the LMH1297 as an adaptive equalizer (EQ mode) or as a cable driver (CD mode). See 表 8-2 for details. EQ/CD_SEL is internally pulled low by default (EQ mode).
HOST_EQ0	9	I, 4-LEVEL	HOST_EQ0 selects the driver output amplitude and de-emphasis level for OUT0± (in EQ mode) and equalizer setting for IN0± (in CD mode). See 表 8-5 and 表 8-10 for details.
MODE_SEL	12	I, 4-LEVEL	MODE_SEL enables the SPI or SMBus serial control interface. See 表 8-11 for details.
SDI_OUT_SEL	14	I, LVCMOS	SDI_OUT_SEL enables the use of the 75-Ω output driver at SDI_OUT±. See 表 8-3 for details. SDI_OUT_SEL is internally pulled high by default (SDI_OUT disabled).
OUT_CTRL	17	I, 4-LEVEL	OUT_CTRL selects the signal being routed to the output. It is used to enable or bypass the reclocker and to enable or bypass the cable equalizer. See 表 8-7 for details.
SDI_VOD	24	I, 4-LEVEL	SDI_VOD selects one of four output amplitudes for the cable drivers at SDI_IO± and SDI_OUT±. See 表 8-8 for details.
LOCK_N	27	O, LVCMOS, OD	LOCK_N is the reclocker lock indicator. LOCK_N is pulled low when the reclocker has acquired lock condition. LOCK_N is a 3.3-V tolerant, open-drain output. It requires an external resistor to a logic supply. LOCK_N can be reconfigured to indicate Carrier Detector (CD_N) or Interrupt (INT_N) through register programming. See 节 8.3.10.
ENABLE	32	I, LVCMOS	A logic-high at ENABLE enables normal operation for the LMH1297. A logic-low at ENABLE places the LMH1297 in Power-Down mode. ENABLE is internally pulled high by default.
SPI SERIAL CONTROL INTERFACE, MODE_SEL = F (FLOAT)			
SS_N	11	I, LVCMOS	SS_N is the Target Select. When SS_N is at logic Low, it enables SPI access to the LMH1297 target device. SS_N is a 2.5-V LVCMOS input and is internally pulled high by default.
MOSI	13	I, LVCMOS	MOSI is the SPI serial control data input to the LMH1297 target device when the SPI bus is enabled. MOSI is a 2.5-V LVCMOS input. An external pullup resistor is recommended.
MISO	28	O, LVCMOS	MISO is the SPI serial control data output from the LMH1297 target device. MISO is a 2.5-V LVCMOS output.
SCK	29	I, LVCMOS	SCK is the SPI serial input clock to the LMH1297 target device when the SPI interface is enabled. SCK is a 2.5-V LVCMOS input. An external pullup resistor is recommended.
SMBUS SERIAL CONTROL INTERFACE, MODE_SEL = L (1 KΩ TO VSS)			
ADDR0	11	Strap, 4-LEVEL	ADDR[1:0] are 4-level straps, read into the device at power up. They are used to select one of the 16 supported SMBus addresses when SMBus is enabled. See 表 8-12 for details.
SDA	13	I/O, LVCMOS, OD	SDA is the SMBus bidirectional data line to or from the LMH1297 target device when SMBus is enabled. SDA is an open-drain I/O and requires an external pullup resistor to the SMBus termination voltage. SDA is 3.3-V tolerant.
ADDR1	28	Strap, 4-LEVEL	ADDR[1:0] are 4-level straps, read into the device at power up. They are used to select one of the 16 supported SMBus addresses when SMBus is enabled. See 表 8-12 for details.
SCL	29	I/O, LVCMOS, OD	SCL is the SMBus input clock to the LMH1297 target device when SMBus is enabled. It is driven by a LVCMOS open-drain driver from the SMBus controller. SCL requires an external pullup resistor to the SMBus termination voltage. SCL is 3.3-V tolerant.

表 6-1. Pin Functions (continued)

PIN		I/O ⁽¹⁾	DESCRIPTION
NAME	NO.		
RESERVED			
RSV1	10	—	Reserved pins. Do not connect.
RSV2	15		
RSV3	16		
RSV4	25		
RSV5	26		
POWER			
VSS	3, 6, 20	I, Ground	Ground reference.
VDD_CDR	21	I, Power	VDD_CDR powers the reclocker circuitry. It is connected to the same 2.5-V \pm 5% supply as VIN.
VIN	30	I, Power	VIN is connected to an external 2.5-V \pm 5% power supply.
VDD_LDO	31	O, Power	VDD_LDO is the output of the internal 1.8-V LDO regulator. VDD_LDO output requires an external 1- μ F and 0.1- μ F bypass capacitor to VSS. The internal LDO is designed to power internal circuitry only.
EP	—	I, Ground	EP is the exposed pad at the bottom of the RTV package. The exposed pad should be connected to the VSS plane through a 3 \times 3 via array.

(1) I = input, O = output, I/O = input or output, OD = open drain, LVCMOS = 2-state logic, 4-LEVEL = 4-state logic

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage (VIN, VDD_CDR)	- 0.5	2.75	V
Input voltage for 4-level pins	- 0.5	2.75	V
Input/output voltage for 2-level control pins	- 0.5	2.75	V
SMBus input/output voltage (SDA, SCL)	- 0.5	4	V
SPI input/output voltage (SS_N, MISO, MOSI, and SCK)	- 0.5	2.75	V
High-speed input/output voltage (IN0±, SDI_IO±, OUT0±, SDI_OUT±)	- 0.5	2.75	V
Input current (IN0±, SDI_IO±)	- 30	30	mA
Operating junction temperature		125	°C
Storage temperature, T _{stg}	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins except 13, 27, and 29	±6000	V
		Pins 13, 27, and 29	±5000	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾		±1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT	
Supply voltage	VIN, VDD_CDR to VSS	2.375	2.5	2.625	V	
VDD _{SMBUS}	SMBus: SDA, SCL open-drain termination voltage	2.375		3.6	V	
V _{SDI_IO_LAUNCH}	Source launch amplitude before coaxial cable to SDI_IO+	Normal mode	0.72	0.8	0.88	Vp-p
		Splitter mode	0.36	0.4	0.44	
V _{IN0_LAUNCH}	Source differential launch amplitude	Before 5-inch board trace to IN0±	300		850	mVp-p
		Before 20-inch board trace to IN0±	650		1000	
T _{JUNCTION}	Operating junction temperature			110	°C	
T _{AMBIENT}	Ambient temperature	- 40	25	85	°C	
NT _{psmax}	Maximum supply noise ⁽¹⁾	50 Hz to 1 MHz, sinusoidal		< 20	mVp-p	
		1.1 MHz to 50 MHz, sinusoidal		< 10		

- (1) The sum of the DC supply voltage and AC supply noise should not exceed the recommended supply voltage range.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LMH1297	UNIT
		RTV (QFN)	
		32 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	32.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	15.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	6.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	6.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1.7	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER						
$P_{D_{EQ_MODE}}$	Power dissipation, EQ Mode, Measured with PRBS10, CDR Locked to 11.88 Gbps, VOD = default, HEO/VEO lock monitor disabled	SDI_OUT± disabled OUT0± enabled		275		mW
		SDI_OUT± enabled OUT0± enabled		418		mW
$P_{D_{CD_MODE}}$	Power dissipation, CD Mode, Measured with PRBS10, CDR Locked to 11.88 Gbps, VOD = default, HEO/VEO lock monitor disabled	SDI_IO± enabled SDI_OUT± disabled OUT0± disabled		305		mW
		SDI_IO± enabled SDI_OUT± disabled OUT0± enabled		350		mW
		SDI_IO± enabled SDI_OUT± enabled OUT0± disabled		442		mW
		SDI_IO± enabled SDI_OUT± enabled OUT0± enabled		485		mW
P_{Dz}	Power dissipation, Power Save Mode	EQ Mode, Power Save Mode, ENABLE = H, no signal applied at SDI_IO+		25		mW
		CD Mode, Power Save Mode, ENABLE = H, no signal applied at IN0±		25		mW
$I_{DD_{EQ_MODE}}$	Current consumption, EQ Mode, Measured with PRBS10, CDR Locked to 11.88 Gbps, VOD = default, HEO/VEO lock monitor disabled	SDI_OUT± disabled OUT0± enabled		110	137	mA
		SDI_OUT± enabled OUT0± enabled		167	200	mA

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
IDD _{CD_MODE}	Current consumption, CD Mode, Measured with PRBS10, CDR Locked to 11.88 Gbps, VOD = default, HEO/VEO lock monitor disabled	SDI_IO± enabled SDI_OUT± disabled OUT0± disabled		122	146	mA
		SDI_IO± enabled SDI_OUT± disabled OUT0± enabled		140	166	mA
		SDI_IO± enabled SDI_OUT± enabled OUT0± disabled		177	211	mA
		SDI_IO± enabled SDI_OUT± enabled OUT0± enabled		194	230	mA
IDD _Z	Current consumption, Power Save Mode	EQ Mode, Power Save Mode, ENABLE = H, no signal applied at SDI_IO+		10		mA
		CD Mode, Power Save Mode, ENABLE = H, no signal applied at IN0±		10		mA
IDD _{Z_PD}	Current consumption, Power-Down Mode	EQ Mode, Power-Down Mode, ENABLE = L, no signal applied at SDI_IO+		10	30	mA
		CD Mode, Power-Down Mode, ENABLE = L, no signal applied at IN0±		10	30	
IDD _{TRANS_EQ}	Current consumption, EQ Mode CDR acquiring lock to 11.88 Gbps, VOD = default, HEO/VEO lock monitor enabled	SDI_OUT± disabled OUT0± enabled			205	mA
		SDI_OUT± enabled OUT0± enabled			260	mA
IDD _{TRANS_CD}	Current consumption, CD Mode CDR acquiring lock to 11.88 Gbps, VOD = default, HEO/VEO lock monitor enabled	SDI_IO± enabled SDI_OUT± disabled OUT0± disabled			200	mA
		SDI_IO± enabled SDI_OUT± disabled OUT0± enabled			225	mA
		SDI_IO± enabled SDI_OUT± enabled OUT0± disabled			271	mA
		SDI_IO± enabled SDI_OUT± enabled OUT0± enabled			290	mA
LVC MOS DC SPECIFICATIONS						
V _{IH}	Logic high input voltage	2-level input (SS_N, SCK, MOSI, EQ/ CD_SEL, SDI_OUT_SEL, OUT0_SEL, ENABLE)	0.72 × VIN		VIN + 0.3	V
		2-level input (SCL, SDA)	0.7 × VIN		3.6	V
V _{IL}	Logic low input voltage	2-level input (SS_N, SCK, MOSI, EQ/ CD_SEL, SDI_OUT_SEL, OUT0_SEL, ENABLE, SCL, SDA)	0		0.3 × VIN	V
V _{OH}	Logic high output voltage	IOH = - 2 mA, (MISO)	0.8 × VIN		VIN	V
V _{OL}	Logic low output voltage	IOL = 2 mA, (MISO)	0		0.2 × VIN	V
		IOL = 3 mA, (LOCK_N, SDA)			0.4	V

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{IH}	Input high leakage current (V _{input} = V _{IN})	LVC MOS (EQ/CD_SEL, SDI_OUT_SEL, ENABLE)			15	μA
		LVC MOS (OUT0_SEL)			65	μA
		LVC MOS (LOCK_N)			10	μA
		SPI mode: LVC MOS (SS_N, SCK, MOSI)			15	μA
		SMBus mode: LVC MOS (SCL, SDA)			10	μA
I _{IL}	Input low leakage current (V _{input} = GND)	LVC MOS (EQ/CD_SEL, SDI_OUT_SEL, ENABLE)	- 50			μA
		LVC MOS (OUT0_SEL)	- 15			μA
		LVC MOS (LOCK_N)	- 10			μA
		SPI mode: LVC MOS (SCK, MOSI)	- 15			μA
		SPI mode: LVC MOS (SS_N)	- 50			μA
		SMBus mode: LVC MOS (SCL, SDA)	- 10			μA
4-LEVEL LOGIC DC SPECIFICATIONS (APPLY TO ALL 4-LEVEL INPUT CONTROL PINS)						
V _{LVL_H}	LEVEL-H input voltage	Measured voltage at 4-level pin with external 1 kΩ to V _{IN}		V _{IN}		V
V _{LVL_F}	LEVEL-F default voltage	Measured voltage 4-level pin at default		$\frac{2}{3} \times V_{IN}$		V
V _{LVL_R}	LEVEL-R input voltage	Measured voltage at 4-level pin with external 20 kΩ to V _{SS}		$\frac{1}{3} \times V_{IN}$		V
V _{LVL_L}	LEVEL-L input voltage	Measured voltage at 4-level pin with external 1 kΩ to V _{SS}		0		V
I _{IH}	Input high leakage current (V _{input} = V _{IN})	4-levels (HOST_EQ0, MODE_SEL, OUT_CTRL, SDI_VOD)	20	45	80	μA
		SMBus mode: 4-levels (ADDR0, ADDR1)	20	45	80	μA
I _{IL}	Input low leakage current (V _{input} = GND)	4-levels (HOST_EQ0, MODE_SEL, OUT_CTRL, SDI_VOD)	- 160	- 93	- 40	μA
		SMBus mode: 4-levels (ADDR0, ADDR1)	- 160	- 93	- 40	μA
RECEIVER SPECIFICATIONS (SDI_IO+, EQ MODE)						
R _{SDI_IO_TERM}	DC input single-ended termination	SDI_IO+ and SDI_IO- to internal common mode bias	63	75	87	Ω
RL _{SDI_IO_S11}	Input return loss at SDI_IO+ reference to 75 Ω ⁽¹⁾	S11, 5 MHz to 1.485 GHz		- 30		dB
		S11, 1.485 GHz to 3 GHz		- 22		dB
		S11, 3 GHz to 6 GHz		- 12		dB
		S11, 6 GHz to 12 GHz		- 8		dB
V _{SDI_IO_CM}	SDI_IO+ DC common-mode voltage	Input DC common-mode voltage at SDI_IO+ or SDI_IO- to GND		1.4		V
V _{SDI_IO_WANDER}	Input DC wander	SD, input signal at SDI_IO+, Input launch amplitude = 800 mVp-p		100		mVp-p
		HD, 3G, 6G, 12G, input signal at SDI_IO+, Input launch amplitude = 800 mVp-p		50		mVp-p
RECEIVER SPECIFICATIONS (IN0±, CD MODE)						
R _{IN0_TERM}	DC input differential termination	Measured across IN0+ to IN0-	80	100	120	Ω
RL _{IN0_SDD11}	Input differential return loss ⁽¹⁾	SDD11, 10 MHz - 2.8 GHz		- 22		dB
		SDD11, 2.8 GHz - 6 GHz		- 16		dB
		SDD11, 6 GHz - 11.1 GHz		- 10		dB

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
RL _{IN0_SCD11}	Differential to common-mode input conversion ⁽¹⁾	SCD11, 10 MHz to 11.1 GHz		- 21		dB
V _{IN0_CM}	DC common-mode voltage	Input common-mode voltage at IN0+ or IN0- to GND		2.06		V
CD _{ON_IN0}	Signal detect (default) Assert ON threshold level for IN0±	11.88 Gbps PRBS10 pattern		20		mVp-p
CD _{OFF_IN0}	Signal detect (default) Deassert OFF threshold level for IN0±	11.88 Gbps PRBS10 pattern		18		mVp-p
DRIVER OUTPUT (SDI_IO+ AND SDI_OUT+, CD MODE)						
R _{OUT_TERM}	DC output single-ended termination	SDI_IO+ and SDI_IO-, SDI_OUT+ and SDI_OUT- to VIN	63	75	87	Ω
VOD _{CD_OUTP}	Output single-ended output voltage	Measure AC signal at SDI_IO+ and SDI_OUT+, with SDI_IO- and SDI_OUT- AC terminated with 75 Ω SDI_VOD = H		840		mVp-p
		SDI_VOD = F	720	800	880	mVp-p
		SDI_VOD = R		880		mVp-p
		SDI_VOD = L		760		mVp-p
VOD _{CD_OUTN}	Output single-ended output voltage	Measure AC signal at SDI_IO- and SDI_OUT-, with SDI_IO+ and SDI_OUT+ AC terminated with 75 Ω SDI_VOD = H		840		mVp-p
		SDI_VOD = F	720	800	880	mVp-p
		SDI_VOD = R		880		mVp-p
		SDI_VOD = L		760		mVp-p
PRE _{CD_OUTP}	Output pre-emphasis	Output pre-emphasis boost amplitude at SDI_IO+ and SDI_OUT+, programmed to maximum setting through register, measured at SDI_VOD=F		2		dB
PRE _{CD_OUTN}	Output pre-emphasis	Output pre-emphasis boost amplitude at SDI_IO- and SDI_OUT-, programmed to maximum setting through register, measured at SDI_VOD=F		2		dB
t _{R_F_SDI}	Output rise and fall time ⁽¹⁾	Measured with PRBS10 pattern, default VOD at 20% - 80% amplitude, default pre-emphasis enabled 11.88 Gbps		34	42	ps
		5.94 Gbps		36	43	ps
		2.97 Gbps		59	67	ps
		1.485 Gbps		60	73	ps
		270 Mbps	400	550	700	ps
t _{R_F_DELTA}	Output rise and fall time mismatch ⁽¹⁾	Measured with PRBS10 pattern, default VOD at 20% - 80% amplitude, default pre-emphasis enabled 11.88 Gbps		3	18	ps
		5.94 Gbps		2.7	12	ps
		2.97 Gbps		0.8	11	ps
		1.485 Gbps		0.8	12	ps
		270 Mbps		72	150	ps

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OVERSHOOT}	Output overshoot or undershoot ⁽¹⁾	Measured with PRBS10 pattern, default VOD, default pre-emphasis enabled ⁽³⁾ 12G/6G/3G/HD/SD		5%		
V _{DC_OFFSET}	DC offset	12G/6G/3G/HD/SD		±0.2		V
V _{DC_WANDER}	DC wander	3G/HD/SD with EQ pathological pattern		20		mV
RL _{CD_S22}	Output return loss at SDI_IO+ and SDI_OUT+ reference to 75 Ω ⁽¹⁾	S22, 5 MHz to 1.485 GHz		- 25		dB
		S22, 1.485 GHz to 3 GHz		- 22		dB
		S22, 3 GHz to 6 GHz		- 12		dB
		S22, 6 GHz to 12 GHz		- 8		dB
DRIVER OUTPUT (OUT0±, EQ AND CD MODE)						
R _{OUT0_TERM}	DC output differential termination	Measured across OUT0+ and OUT0 -	80	100	120	Ω
V _{ODOUT0}	Output differential voltage at OUT0±	Measured with 8T pattern HOST_EQ0 = H		410		mVp-p
		HOST_EQ0 = F	485	560	620	mVp-p
		HOST_EQ0 = R		635		mVp-p
		HOST_EQ0 = L		810		mVp-p
V _{ODOUT0_DE}	De-emphasized output differential voltage at OUT0±	Measured with 8T pattern HOST_EQ0 = H		410		mVp-p
		HOST_EQ0 = F		550		mVp-p
		HOST_EQ0 = R		545		mVp-p
		HOST_EQ0 = L		532		mVp-p
t _R /t _F	Output rise and fall time	Measured with 8T Pattern, 20% - 80% amplitude		45		ps
RL _{OUT0-SDD22}	Output differential return loss ⁽¹⁾	Measured with the device powered up and outputs a 10-MHz clock signal SDD22, 10 MHz - 2.8 GHz		- 24		dB
		SDD22, 2.8 GHz - 6 GHz		- 16		dB
		SDD22, 6 GHz - 11.1 GHz		- 15		dB
RL _{OUT0-SCC22}	Output common-mode return loss ⁽¹⁾	Measured with the device powered up and outputs a 10-MHz clock signal. SCC22, 10 MHz - 4.75 GHz		- 12		dB
		SCC22, 4.75 GHz - 11.1 GHz		- 9		dB
V _{OUT0_CM}	AC common-mode voltage on OUT0± ⁽¹⁾	Default setting, PRBS31, 11.88 Gbps		8		mV (rms)
RELOCKER OUTPUT JITTER (EQ MODE)						
T _{JEQ_MODE}	Total jitter, relocked output ⁽¹⁾ ⁽²⁾	Measured at OUT0±, with SDI_OUT disabled (BER ≤ 1E-12), PRBS10, TX launch amplitude = 800 mVp-p before cable to SDI_IO+ 11.88 Gbps: 75-m Belden 1694A		0.14	0.18	Ulp-p
		5.94 Gbps: 120-m Belden 1694A		0.1		
		2.97 Gbps: 200-m Belden 1694A		0.1		
		1.485 Gbps: 300-m Belden 1694A		0.1		
		270 Mbps: 600-m Belden 1694A		0.11		

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
T _{JRAW}	Total jitter, with CDR bypassed	Measured at OUT0±, with SDI_OUT disabled (BER ≤ 1E-12), PRBS10, TX launch amplitude = 800 mVp-p before cable to SDI_IO+ 125 Mbps: 600-m Belden 1694A		0.2		UIp-p
RELOCKER OUTPUT JITTER (CD MODE)						
A _{JCD_MODE}	Alignment jitter ⁽¹⁾	Measured at SDI_IO+ and SDI_OUT+, OUT0± disabled PRBS10, 3G/HD/SD12G/6G/3G/HD/SD		0.1	0.14	UI
TM _{JCD_MODE}	Timing jitter ⁽¹⁾	Measured at SDI_IO+ and SDI_OUT+, OUT0± disabled PRBS10, 12G/6G/3G/HD/SD		0.45		UI
RELOCKER SPECIFICATIONS (EQ MODE UNLESS OTHERWISE SPECIFIED)						
LOCK _{RATE}	Reclocker lock data rates	SMPTE 12G, /1		11.88		Gbps
		SMPTE 12G, /1.001		11.868		Gbps
		SMPTE 6G, /1		5.94		Gbps
		SMPTE 6G, /1.001		5.934		Gbps
		SMPTE 3G, /1		2.97		Gbps
		SMPTE 3G, /1.001		2.967		Gbps
		SMPTE HD, /1		1.485		Gbps
		SMPTE HD, /1.001		1.4835		Gbps
	SMPTE SD, /1		270		Mbps	
BYPASS _{RATE}	Reclocker automatically goes to bypass	MADI		125		Mbps
BW _{PLL}	PLL Bandwidth	Applied 0.2 UI input sinusoidal jitter, measure - 3-dB bandwidth on input-to-output jitter transfer 11.88 Gbps		13		MHz
		5.94 Gbps		7		MHz
		2.97 Gbps		5		MHz
		1.485 Gbps		3		MHz
		270 Mbps		1		MHz
J _{PEAKING}	PLL jitter peaking	11.88 Gbps, 5.94 Gbps, 2.97 Gbps, 1.485 Gbps, 270 Mbps		<0.3		dB
J _{TOL_IN}	SDI_IO+ input jitter tolerance	Sinusoidal jitter tolerance, tested at 3G, 6G and 12G, SJ amplitude swept from 1 MHz to 80 MHz, tested at BER ≤ 1E-12, cable equalizer at SDI_IO+ bypassed		0.65		UI
T _{LOCK}	Lock time	SMPTE supported data rates, disable HEO/VEO monitor, cable equalizer at SDI_IO+ bypassed		5		ms
T _{ADAPT}	EQ adapt time at EQ Mode	Adaptation time for cable equalizer at SDI_IO+, reclocker bypassed		5		ms
TEMP _{LOCK}	VCO temperature lock range	Measured with temperature ramp of 5°C per min, ramp up and down, - 40°C to 85°C operating range at 11.88 Gbps		125		°C

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
TLAT _{EQ_MODE}	Reclocker latency at EQ Mode	Measured from SDI_IO+ to OUT0, 11.88 Gbps, SDI_IO+, 75-m Belden 1694A at SDI_IO+		1.4 UI + 465		ps
		Measured from SDI_IO+ to SDI_OUT+, 11.88 Gbps, SDI_IO+, 75-m Belden 1694A at SDI_IO+		1.7 UI + 415		ps
TLAT _{CD_MODE}	Reclocker latency at CD Mode	Measured from IN0± to SDI_IO+, 11.88 Gbps		1.5 UI + 175		ps
		Measured from IN0± to SDI_OUT+, 11.88 Gbps		1.6 UI + 130		ps

- (1) This parameter is measured with the LMH1297EVM (Evaluation board for LMH1297).
- (2) This limit is ensured by bench characterization and is not production tested.
- (3) $V_{\text{OVERSHOOT}}$ overshoot/undershoot maximum measurements are largely affected by the PCB layout and input test pattern. The maximum value specified in # 7.5 for $V_{\text{OVERSHOOT}}$ is based on bench evaluation across temperature and supply voltages with the LMH1297EVM.

7.6 Recommended SMBus Interface Timing Specifications

over recommended operating supply and temperature ranges unless otherwise specified⁽¹⁾

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
F _{SCL}	SMBUS SCL frequency		10		400	kHz
T _{BUF}	Bus free time between stop and start condition	See 图 7-1 .	1.3			μs
T _{HD:STA}	Hold time after (repeated) start condition.	After this period, the first clock is generated.	0.6			μs
T _{SU:STA}	Repeated start condition setup time	See 图 7-1 .	0.6			μs
T _{SU:STO}	Stop condition setup time	See 图 7-1 .	0.6			μs
T _{HD:DAT}	Data hold time	See 图 7-1 .	0			ns
T _{SU:DAT}	Data setup time	See 图 7-1 .	100			ns
T _{LOW}	Clock low period	See 图 7-1 .	1.3			μs
T _{HIGH}	Clock high period	See 图 7-1 .	0.6			μs
T _R	Clock and data rise time	See 图 7-1 .			300	ns
T _F	Clock and data fall time	See 图 7-1 .			300	ns
T _{POR}	SMBus ready time after POR	Time from minimum VDDIO to SMBus valid write or read access			50	ms

- (1) These parameters support SMBus 2.0 specifications.

7.7 Serial Parallel Interface (SPI) Timing Specifications

over recommended operating supply and temperature ranges unless otherwise specified^{(1) (2)}

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
F _{SCK}	SPI SCK frequency				20	MHz
T _{PH}	SCK pulse width high	See 图 7-2 and 图 7-3	40			% SCK period
T _{PL}	SCK pulse width low		40			% SCK period
T _{SU}	MOSI setup time	See 图 7-2 and 图 7-3	4			ns
T _H	MOSI hold time		4			ns
T _{SSSU}	SS setup time	See 图 7-2 and 图 7-3	14			ns
T _{SSH}	SS hold time		4			ns
T _{SSOF}	SS off time		1			μs

over recommended operating supply and temperature ranges unless otherwise specified^{(1) (2)}

PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
T _{ODZ}	MISO driven-to-tristate time		20		ns
T _{OZD}	MISO tristate-to-driven time	See 图 7-2 and 图 7-3		10	ns
T _{OD}	MISO output delay time		15		ns

- (1) Typical SPI load capacitance is 2 pF.
- (2) It is recommended to initiate SPI access 16 mS after power up.

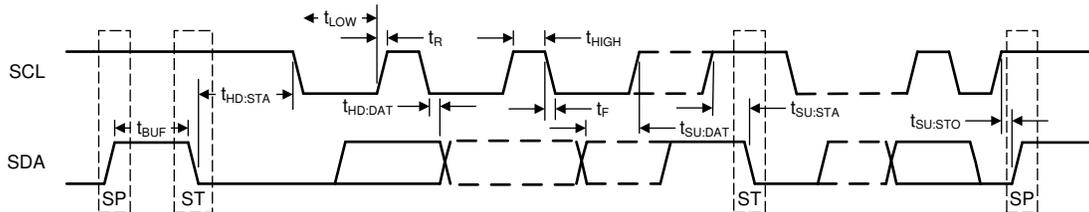


图 7-1. SMBus Timing Parameters

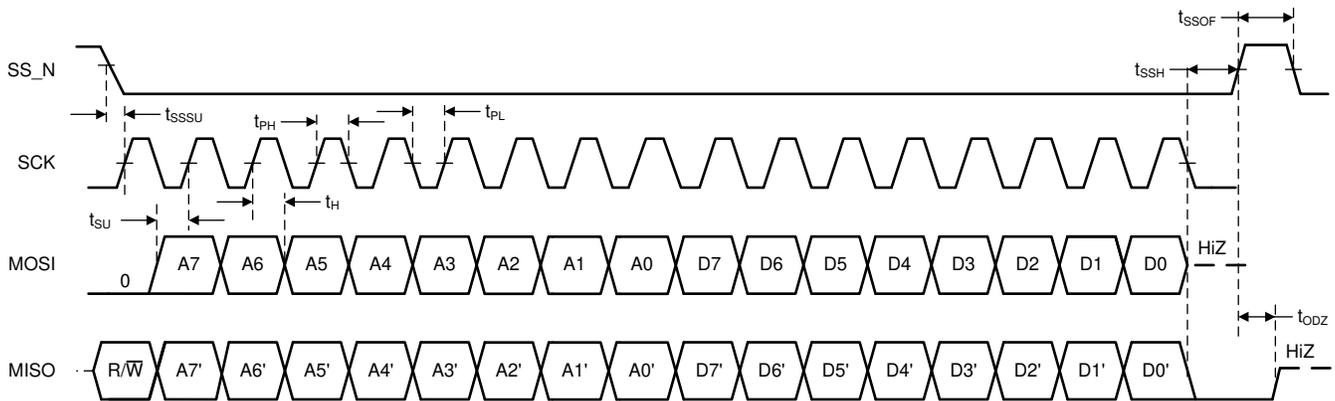


图 7-2. SPI Timing Parameters (Write Operation)

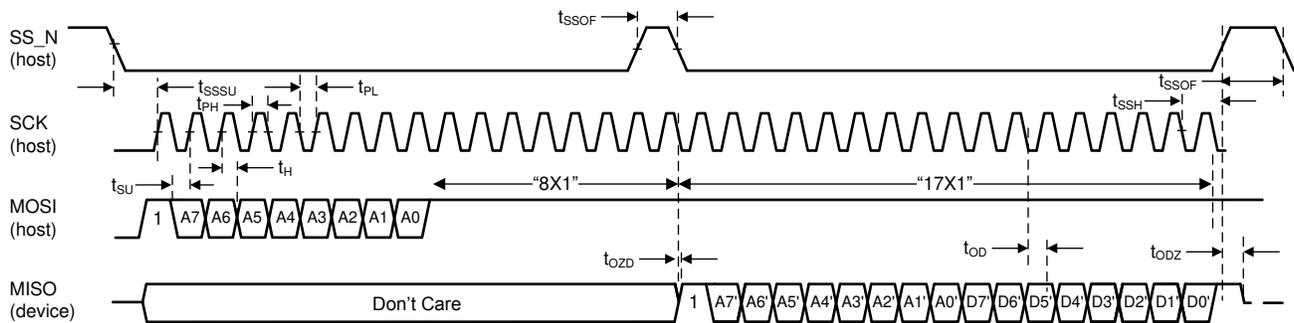


图 7-3. SPI Timing Parameters (Read Operation)

7.8 Typical Characteristics

$T_A = 25^\circ\text{C}$ and $V_{IN} = V_{DD_CDR} = 2.5\text{ V}$ (unless otherwise noted)

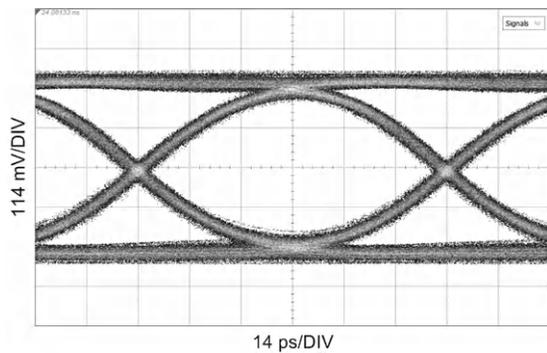


图 7-4. EQ Mode at 11.88 Gbps, Measured at OUT0±, 75-m Belden 1694A Before SDI_IO+

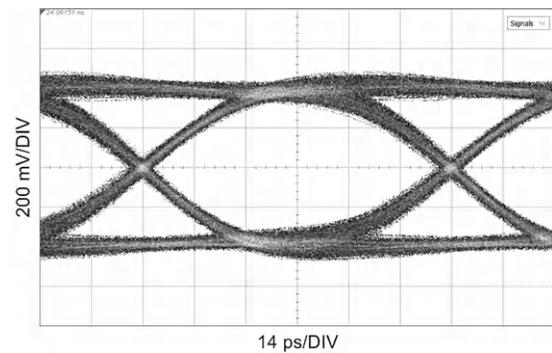


图 7-5. CD Mode at 11.88 Gbps, Measured at SDI_IO+, 20-in. FR4 Before IN0±

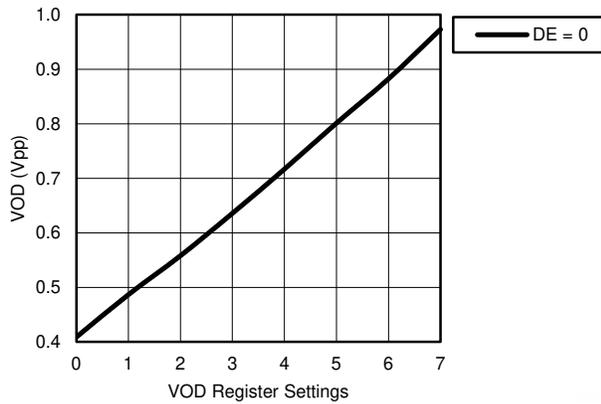


图 7-6. OUT0 VOD vs. OUT0 VOD and DE Register Settings

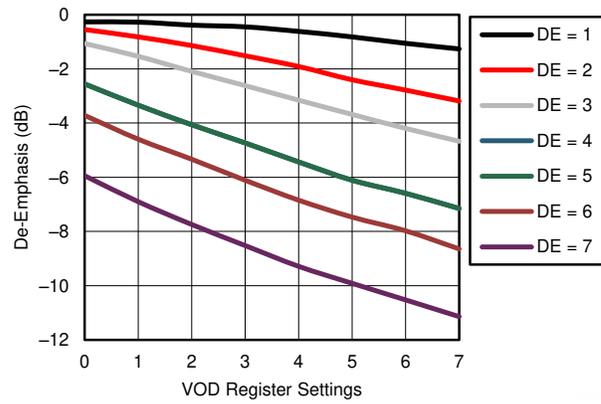
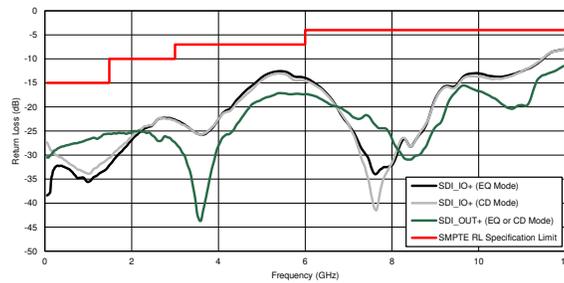


图 7-7. OUT0 De-Emphasis vs. OUT0 VOD and DE Register Settings



Measured with LMH1297EVM

图 7-8. Return Loss (RL) vs Frequency

备注

Only one I/O path can be active at a time. In EQ mode, the cable equalizer at SDI_IO is enabled, and the SDI_IO cable driver is powered down. In CD mode, the cable driver at SDI_IO is enabled, and the SDI_IO cable equalizer is powered down.

8.3 Feature Description

The LMH1297 data path consists of several key blocks as shown in the functional block diagram. These key blocks are:

- [4-Level Input Pins and Thresholds](#)
- [Equalizer \(EQ\) and Cable Driver \(CD\) Mode Control](#)
- [Input Carrier Detect](#)
- [-6-dB Splitter Mode Launch Ampiltude for SDI_IO+ \(EQ Mode Only\)](#)
- [Continuous Time Linear Equalizer \(CTLE\)](#)
- [Clock and Data \(CDR\) Recovery](#)
- [Internal Eye Opening Monitor \(EOM\)](#)
- [Output Function Control](#)
- [Output Driver Control](#)
- [Status Indicators and Interrupts](#)

8.3.1 4-Level Input Pins and Thresholds

The 4-level input configuration pins use a resistor divider to provide four logic states for each control pin. There is an internal 30-k Ω pullup and a 60-k Ω pulldown connected to the control pin that sets the default voltage at $2/3 \times V_{IN}$. These resistors are combined with the external resistor to achieve the desired voltage level. By using the 1-k Ω pulldown, 20-k Ω pulldown, no connect, and 1-k Ω pullup, the optimal voltage levels for each of the four input states are achieved as shown in [表 8-1](#).

表 8-1. 4-Level Control Pin Settings

LEVEL	SETTING	NOMINAL PIN VOLTAGE
H	Tie 1 k Ω to VIN	VIN
F	Float (leave pin open)	$2/3 \times V_{IN}$
R	Tie 20 k Ω to VSS	$1/3 \times V_{IN}$
L	Tie 1 k Ω to VSS	0

Typical 4-Level Input Thresholds:

- Internal Threshold between L and R = $0.2 \times V_{IN}$
- Internal Threshold between R and F = $0.5 \times V_{IN}$
- Internal Threshold between F and H = $0.8 \times V_{IN}$

8.3.2 Equalizer (EQ) and Cable Driver (CD) Mode Control

The input and output signal flow of the LMH1297 is determined by the EQ/CD_SEL, OUT0_SEL, and SDI_OUT_SEL pins.

8.3.2.1 EQ/CD_SEL Control

The EQ/CD_SEL pin selects the I/O as either an input (EQ mode) or an output (CD mode). The logic level applied to the EQ/CD_SEL pin automatically powers down the unused I/O direction. For example, if the LMH1297 is in EQ mode (EQ/CD_SEL = L), then the SDI_IO cable driver is powered down.

表 8-2. EQ/CD_SEL Pin Settings

EQ/CD_SEL	INPUT	MODE	NOTES
L	SDI_IO+	EQ mode	75-Ω video input to SDI_IO+. OUT0± automatically enabled. SDI_IO Cable Driver powered down.
H	IN0±	CD mode	100-Ω input to IN0±. SDI_IO+ enabled as a cable driver output. SDI_OUT programmable as a secondary cable driver output. SDI_IO Equalizer powered down.

The EQ/CD_SEL pin should be strapped at power up for normal operation. After power up, the EQ/CD_SEL pin state can be dynamically changed from EQ mode to CD mode and vice versa. When changing the EQ/CD_SEL state after power up, the signal flow to the reclocker is momentarily disturbed, and the chip automatically initiates a CDR reset to relock to the new input signal.

8.3.2.2 OUT0_SEL and SDI_OUT_SEL Control

The OUT0_SEL and SDI_OUT_SEL pins work in conjunction with the EQ/CD_SEL pin to select the LMH1297 data-path routes. 表 8-3 shows all possible signal path combinations and typical use cases for each configuration.

表 8-3. LMH1297 Signal Path Combinations

EQ/CD_SEL (MODE)	OUT0_SEL	SDI_OUT_SEL	INPUT	MAIN OUTPUT	LINE SIDE LOOP-THRU OUTPUT	HOST SIDE LOOP-BACK OUTPUT	TYPICAL APPLICATION
L (EQ mode)	X	H	SDI_IO+	OUT0±			Adaptive cable equalizer
	X	L	SDI_IO+	OUT0±	SDI_OUT±		Adaptive cable equalizer with line-side loop-through output
H (CD mode)	H	H	IN0±	SDI_IO+			Single cable driver
	H	L	IN0±	SDI_IO+	SDI_OUT±		Dual cable drivers
	L	H	IN0±	SDI_IO+		OUT0±	Single cable driver with host-side loop-back enabled
	L	L	IN0±	SDI_IO+	SDI_OUT±	OUT0±	Dual cable drivers with host-side loop-back enabled

8.3.3 Input Carrier Detect

SDI_IO (in EQ mode) and IN0 have a carrier detect circuit to monitor the presence or absence of an input signal. When the input signal amplitude for the selected input exceeds the carrier detect assert threshold, the LMH1297 operates in normal operation mode.

In the absence of an input signal, the LMH1297 automatically goes into Power Save mode to conserve power dissipation. When a valid signal is detected, the LMH1297 automatically exits Power Save mode and returns to the normal operation mode. If the ENABLE pin is pulled low, the LMH1297 is forced into Power-Down mode. In Power Save mode, both the carrier detect circuit and the serial interface remain active. In Power-Down mode, only the serial interface remains active.

Users can monitor the status of the carrier detect through register programming. This can be done either by configuring the LOCK_N pin to output the CD_N status or by monitoring the carrier detect status register.

表 8-4. Input Carrier Detect Modes of Operation

ENABLE	EQ/CD_SEL	SIGNAL INPUT	OPERATING MODE
H	L	75-Ω video input at SDI_IO+	EQ mode, normal operation Carrier detector at SDI_IO+ Serial interface active OUT0 automatically enabled, regardless of OUT0_SEL setting
H	L	No signal at SDI_IO+	Power Save mode Carrier detector at SDI_IO+ Serial interface active

表 8-4. Input Carrier Detect Modes of Operation (continued)

ENABLE	EQ/CD_SEL	SIGNAL INPUT	OPERATING MODE
H	H	100-Ω signal input at IN0±	CD mode, normal operation Carrier detector at IN0± Serial interface active
H	H	No signal at IN0±	Power Save mode Carrier detector at IN0± Serial interface active
L	X	Input signal ignored	Power Down mode Forced device power down Serial interface active

8.3.4 - 6-dB Splitter Mode Launch Amplitude for SDI_IO+ (EQ Mode Only)

When placed in EQ mode, the LMH1297 equalizes data transmitted into SDI_IO through a coaxial cable driven by a SMPTE compatible cable driver with launch amplitude of 800 mVp-p ± 10%. In applications where a 1:2 passive splitter is used, the signal amplitude is reduced by half due to the 6-dB insertion loss of the splitter. The LMH1297 can support - 6-dB splitter mode for the SDI_IO input through register control. For more information, refer to the [LMH1297 Programming Guide](#).

8.3.5 Continuous Time Linear Equalizer (CTLE)

The LMH1297 has two continuous time linear equalizer (CTLE) blocks, one for SDI_IO in EQ mode and another for IN0 in CD mode. The CTLE compensates for frequency-dependent loss due to the transmission media prior to the device input. The CTLE accomplishes this by applying variable gain to the input signal, thereby boosting higher frequencies more than lower frequencies. The CTLE block extends the signal bandwidth, restores the signal amplitude, and reduces ISI caused by the transmission medium.

8.3.5.1 Line-Side Adaptive Cable Equalizer (SDI_IO+ in EQ mode)

If the LMH1297 is placed in EQ mode (EQ/CD_SEL = L), adaptive cable equalization is enabled for SDI_IO. While the LMH1297 is in EQ mode, IN0 EQ is powered down.

SDI_IO has an on-chip 75-Ω termination to the input common-mode voltage and includes a series return loss compensation network for meeting stringent SMPTE return loss requirements (see [图 7-8](#)). The cable equalizer is designed with high gain and low noise circuitry to compensate for the insertion loss of a coaxial cable (such as Belden 1694A), which is widely used in broadcast video infrastructures.

8.3.5.2 Host-Side Adaptive PCB Trace Equalizer (IN0± in CD Mode)

If the LMH1297 is placed in CD mode (EQ/CD_SEL = H), then PCB trace equalization is enabled for IN0. While the LMH1297 is in CD mode, SDI_IO EQ is powered down.

IN0 has an on-chip 100-Ω termination and is designed for AC coupling, requiring a 4.7-μF, AC-coupling capacitor for minimizing base-line wander. The PCB equalizer can compensate up to 20 inches of board trace at data rates up to 11.88 Gbps. There are two adapt modes for IN0: AM0 manual mode and AM1 adaptive mode. In AM0 manual mode, fixed EQ boost settings are applied through user-programmable control. In AM1 adaptive mode, state machines automatically find the optimal EQ boost from a set of 16 predetermined settings defined in Registers 0x40-0x4F.

In CD mode, the HOST_EQ0 pin determines the IN0 adapt mode and EQ boost level. For normal operation, HOST_EQ0 = F is recommended. HOST_EQ0 pin logic settings are shown in [表 8-5](#). These HOST_EQ0 pin settings can be overridden by register control. For more information, refer to the [LMH1297 Programming Guide](#).

表 8-5. HOST_EQ0 Pin EQ Settings in CD mode (EQ/CD_SEL = H)

HOST_EQ0 ⁽¹⁾	IN0± EQ BOOST ⁽²⁾	RECOMMENDED BOARD TRACE IN0± ⁽³⁾
H	All Rates: AM0 Manual mode, EQ=0x00	< 1 inch
F	Normal Operation 12G to 3G Rates: AM1 Adaptive mode 1.5G, 270M Rates: AM0 Manual mode, EQ= 0x00	0-20 inches
R	All Rates: AM0 Manual mode, EQ=0x80	10-15 inches
L	All Rates: AM0 Manual mode, EQ=0x90	20 inches

- (1) The HOST_EQ0 pin is also used to set OUT0 VOD and de-emphasis values. See [节 8.3.9.2](#) for more information.
- (2) When the LMH1297 is in EQ mode, IN0 EQ settings are ignored, because IN0 EQ is powered down.
- (3) Recommended board trace at 11.88 Gbps.

8.3.6 Clock and Data (CDR) Recovery

After the input signal passes through the CTLE, the equalized data is fed into the clock and data recovery (CDR) block. Using an internal PLL, the CDR locks to the incoming equalized data and recovers a clean internal clock to re-sample the equalized data. The LMH1297 CDR is able to tolerate high input jitter, tracking low-frequency input jitter below the PLL bandwidth while reducing high-frequency input jitter above the PLL bandwidth. The supported data rates are listed in [表 8-6](#).

表 8-6. Supported Data Rates

INPUT	DATA RATE	RELOCKER
SDI_IO+ (EQ mode), IN0± (CD mode)	11.88 Gbps, 5.94 Gbps, 2.97 Gbps, 1.485 Gbps, 270 Mbps ⁽¹⁾	Enable
	125 Mbps	Bypass

(1) The LMH1297 supports divide-by-1.001 lock rates for 11.88 Gbps, 5.94 Gbps, 2.97 Gbps, and 1.485 Gbps.

8.3.7 Internal Eye Opening Monitor (EOM)

The LMH1297 has an on-chip eye opening monitor (EOM) that can be used to analyze, monitor, and diagnose the post-equalized waveform, just prior to the CDR reclocker. The EOM is operational for 2.97 Gbps and higher data rates.

The EOM monitors the post-equalized waveform in a time window that spans one unit interval and a configurable voltage range that spans up to ± 400 mV. The time window and voltage range are divided into 64 steps, so the result of the eye capture is a 64×64 matrix of hits, where each point represents a specific voltage and phase offset relative to the main data sampler. The number of hits registered at each point needs to be taken in context with the total number of bits observed at that voltage and phase offset to determine the corresponding probability for that point.

The resulting 64×64 matrix produced by the EOM can be processed by software and visualized in a number of ways. [图 8-2](#) and [图 8-3](#) show two common ways to visualize this data. These diagrams depict examples of eye monitor plots implemented by software. The first plot is an example using the EOM data to plot a basic eye using ASCII characters, which can be useful for diagnostic software. The second plot shows the first derivative of the EOM data, revealing the density of hits and the actual waveforms and crossings that comprise the eye.

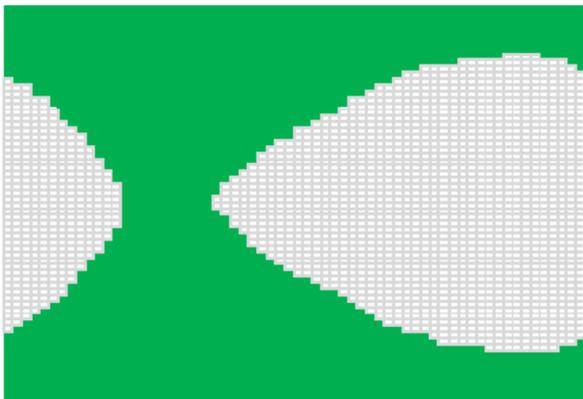


图 8-2. Internal Input Eye Monitor Plot

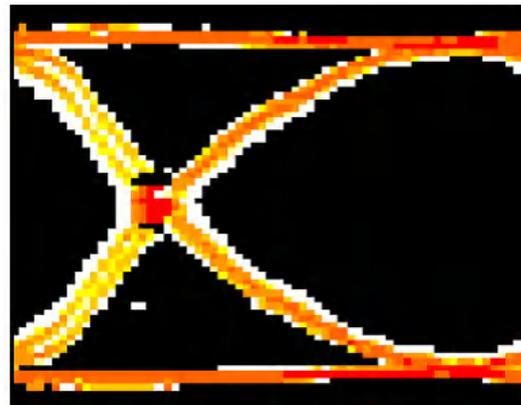


图 8-3. Internal Eye Monitor Hit Density Plot

A common measurement performed by the EOM is the horizontal and vertical eye opening. The horizontal eye opening (HEO) represents the width of the post-equalized eye at 0-V differential amplitude, measured in unit intervals or picoseconds (ps). The vertical eye opening (VEO) represents the height of the post-equalized eye, measured midway between the mean zero crossing of the eye. This position in time approximates the CDR sampling phase. HEO and VEO measurements can be read back through register control.

8.3.8 Output Function Control

The LMH1297 output function control for data routed to outputs SDI_IO (in CD mode), SDI_OUT, and OUT0 is configured by the OUT_CTRL pin. The OUT_CTRL pin determines whether to bypass the input equalizer, reclocker, or both. In normal operation (OUT_CTRL = F), both input equalizer and reclocker are enabled.

表 8-7 lists the OUT_CTRL pin logic settings. These settings can be overridden through register control by applying the appropriate override bit values. For more information, refer to the [LMH1297 Programming Guide](#).

表 8-7. OUT_CTRL Settings for Bypass Modes

EQ/CD_SEL (MODE)	OUT_CTRL	SDI_IO+ CABLE EQUALIZER	IN0± PCB EQUALIZER	RELOCKER	SUMMARY
L (EQ mode)	H	Bypass	N/A	Enable	Input SDI_IO cable equalizer bypassed Reclocker enabled
	F	Enable	N/A	Enable	Normal operation Input SDI_IO cable equalizer enabled Reclocker enabled
	R	Bypass	N/A	Bypass	Input SDI_IO cable equalizer bypassed Reclocker bypassed
	L	Enable	N/A	Bypass	Input SDI_IO cable equalizer enabled Reclocker bypassed
H (CD mode)	H, F	N/A	Enable	Enable	Normal operation Input IN0 equalizer enabled Reclocker enabled
	R, L	N/A	Enable	Bypass	Input IN0 equalizer enabled in AM0 manual mode. IN0 EQ settings configurable by HOST_EQ0 pin. Reclocker bypassed

8.3.9 Output Driver Control

8.3.9.1 Line-Side Output Cable Driver (SDI_IO+ in CD mode, SDI_OUT+ in EQ or CD mode)

The LMH1297 has two output cable driver (CD) blocks, one for SDI_IO in CD mode and another for SDI_OUT. These SDI outputs are designed to drive 75-Ω single-ended coaxial cables at data rates up to 11.88 Gbps. Both SDI_IO and SDI_OUT feature an integrated 75-Ω termination and return loss compensation network for meeting stringent SMPTE return loss requirements (see 图 7-8).

8.3.9.1.1 Output Amplitude (VOD)

In CD mode (EQ/CD_SEL = H), SDI_IO is enabled as an SDI cable driver output. In either CD or EQ mode, SDI_OUT is an SDI cable driver output. In EQ mode, SDI_OUT serves as a loop-through output, and in CD mode, SDI_OUT serves as a secondary cable driver output.

SDI_IO (in CD mode) and SDI_OUT are designed for transmission across 75-Ω single-ended impedance. The nominal SDI cable driver output amplitude (VOD) is 800 mVp-p single-ended. In the presence of long output cable lengths or crosstalk, the SDI_VOD pin can be used to optimize the cable driver output with respect to the nominal amplitude. 表 8-8 details VOD settings that can be applied to both SDI_IO and SDI_OUT. The SDI_VOD pin can be overridden through register control. In addition, the nominal VOD amplitude can be changed by register control. For more information, refer to the [LMH1297 Programming Guide](#).

表 8-8. SDI_VOD Settings for Line-Side Output Amplitude

SDI_VOD	DESCRIPTION
H	about +5% of nominal
F	800 mVp-p (nominal)
R	about +10% of nominal
L	about - 5% of nominal

8.3.9.1.2 Output Pre-Emphasis

In addition to SDI cable driver VOD control, the LMH1297 can add pre-emphasis on the cable driver output to improve output signal integrity when the reclocker recovers a UHD (12G, 6G) or HD (3G, 1.5G) input data rate. By default, the LMH1297 in CD mode automatically enables pre-emphasis to SDI_IO at UHD (12G, 6G) rates, and pre-emphasis is disabled at SDI_IO for all other data rates. To minimize the effects of crosstalk on SDI_IO in either EQ or CD mode, pre-emphasis is disabled by default at SDI_OUT for all data rates. When enabled, the amount of pre-emphasis applied to the cable driver outputs is determined by register control. If the reclocker is bypassed or if the user desires to disable automatic pre-emphasis, pre-emphasis can be enabled manually through register control. For more information, refer to the [LMH1297 Programming Guide](#).

8.3.9.1.3 Output Slew Rate

SMPTE specifications require different output driver rise and fall times depending on the operating data rate. To meet these requirements, the output edge rate of SDI_IO and SDI_OUT is automatically programmed according to the signal recovered by the reclocker. Typical edge rates at the cable driver output are shown in [表 8-9](#).

表 8-9. SDI_IO and SDI_OUT Output Edge Rate

DETECTED DATA RATE	CABLE DRIVER OUTPUT EDGE RATE (TYP)
11.88 Gbps	34 ps
5.94 Gbps	36 ps
2.97 Gbps	59 ps
1.485 Gbps	60 ps
270 Mbps	550 ps

If the reclocker is bypassed, users must program the desired edge rate manually through register control. For more information, refer to the [LMH1297 Programming Guide](#).

8.3.9.1.4 Output Polarity Inversion

Polarity inversion is supported on both SDI_IO and SDI_OUT outputs through register control.

8.3.9.2 Host-Side 100-Ω Output Driver (OUT0± in EQ or CD mode)

OUT0 is a 100-Ω driver output. In EQ mode, OUT0 serves as a host-side output from the SDI_IO cable equalizer. In CD mode, OUT0 serves as a host-side loop-back output. OUT0 also supports polarity inversion.

备注

In EQ mode, OUT0 is enabled by default, regardless of the logic applied to the OUT0_SEL pin.

The driver offers users the capability to select higher output amplitude and de-emphasis levels for longer board trace that connects the drivers to their downstream receivers. Driver de-emphasis provides transmitter equalization to reduce the ISI caused by the board trace.

In EQ mode, the HOST_EQ0 pin determines the output amplitude (VOD) and de-emphasis levels applied to the OUT0 PCB driver. In CD mode, the VOD and de-emphasis levels for OUT0 are set by default to 570 mVp-p and -0.4 dB. These settings can be changed through register control if desired.

[表 8-10](#) details the OUT0 VOD and de-emphasis settings that can be applied. The HOST_EQ0 pin settings can be overridden by register control. When these parameters are controlled by registers, the VOD and de-emphasis levels can be programmed independently. For more information, refer to the [LMH1297 Programming Guide](#).

表 8-10. HOST_EQ0 Pin VOD and DEM Settings

EQ/CD_SEL (MODE)	HOST_EQ ⁽¹⁾	OUT0± VOD (mVp-p)	OUT0± DEM (dB)	RECOMMENDED BOARD TRACE AT OUT0± ⁽²⁾
L (EQ mode)	H	400	0	< 1 inch
	F	570	- 0.4	1-2 inches
	R	660	- 2.1	4-5 inches
	L	830	- 4.4	8-10 inches
H (CD mode)	X	570	- 0.4	1-2 inches

- (1) The HOST_EQ0 pin is also used to set the IN0 EQ values when the LMH1297 is in CD mode. See [§ 8.3.5.2](#) for more information.
- (2) Recommended board trace at 11.88 Gbps.

8.3.10 Status Indicators and Interrupts

The LOCK_N pin is a 3.3-V tolerant, active-low, open-drain output. An external resistor to the logic supply is required. The LOCK_N pin can be configured to indicate reclocker lock, input carrier detect, or an interrupt event.

8.3.10.1 LOCK_N (Lock Indicator)

By default, LOCK_N is the reclocker lock indicator, and this pin asserts low when the LMH1297 achieves lock to a valid SMPTE data rate. The LOCK_N pin functionality can also be configured through register control to indicate CD_N (carrier detect) or INT_N (interrupt) events. For more information about how to reconfigure the LOCK_N pin functionality, refer to the [LMH1297 Programming Guide](#).

8.3.10.2 CD_N (Carrier Detect)

The LOCK_N pin can be reconfigured through register control to indicate a CD_N (carrier detect) event. When configured as a CD_N output, the pin asserts low at the end of adaptation after a valid signal is detected by the carrier detect circuit of the selected input. Under register control, this pin can be reconfigured to indicate CD_N for SDI_IO (in EQ mode) or IN0 (in CD mode). For more information about how to configure the LOCK_N pin for CD_N functionality, refer to the [LMH1297 Programming Guide](#).

8.3.10.3 INT_N (Interrupt)

The LOCK_N pin can be configured to indicate an INT_N (interrupt) event. When configured as an INT_N output, the pin asserts low when an interrupt occurs, according to the programmed interrupt masks. Seven separate masks can be programmed through register control as interrupt sources:

- If there is a loss of signal (LOS) event on SDI_IO in EQ mode (2 separate masks).
- If there is a loss of signal (LOS) event on IN0 in CD mode (2 separate masks).
- If HEO or VEO falls below a certain threshold after CDR is locked (1 mask).
- If a CDR Lock event has occurred (2 separate masks).

INT_N is a sticky bit, meaning that it will flag after an interrupt occurs and will not clear until read-back. Once the Interrupt Status Register is read, the INT_N pin will assert high again. For more information about how to configure the LOCK_N pin for INT_N functionality, refer to the [LMH1297 Programming Guide](#).

8.3.11 Additional Programmability

The LMH1297 supports extended programmability through SPI or SMBus serial control interface. Such added programmability includes:

- Cable EQ Index (CEI)
- Digital MUTE_{REF}

8.3.11.1 Cable EQ Index (CEI)

The Cable EQ Index (CEI) indicates the cable EQ boost index used at SDI_IO+ in EQ mode. CEI is accessible through ConfigIO Page Reg 0x25[5:0]. The 6-bit setting ranges in decimal value from 0 to 55 (000000'b to 110111'b in binary), with higher values corresponding to larger gain applied at the SDI_IO+ input.

8.3.11.2 Digital MUTE_{REF}

Digital MUTE_{REF} ConfigIO Page Reg 0x03[5:0] sets the threshold for the maximum cable length at SDI_IO+ to be equalized before muting the outputs. The MUTE_{REF} register value is directly proportional to the cable length being equalized. MUTE_{REF} is data rate dependent. Follow the steps below to set the MUTE_{REF} register setting for any desired SDI rate:

1. Connect the desired input cable length at which the driver output needs to be muted.
2. Send video patterns to SDI_IO+ at the SD rate (270 Mbps). At SD, the Cable EQ Index (CEI) has the largest dynamic range.
3. Read back ConfigIO Page Reg 0x25[5:0] to record the CEI value.
4. Copy the CEI value, and write this value to Digital MUTE_{REF} ConfigIO Page Reg 0x03[5:0].

8.4 Device Functional Modes

The LMH1297 operates in one of two modes: System Management Bus (SMBus) or Serial Peripheral Interface (SPI) mode. To determine the mode of operation, the proper setting must be applied to the MODE_SEL pin at power up, as detailed in [表 8-11](#).

表 8-11. MODE_SEL Pin Settings

LEVEL	DESCRIPTION
H	Reserved for factory testing - do not use
F	Selects SPI Interface for register access
R	Reserved for factory testing - do not use
L	Selects SMBus Interface for register access

8.4.1 System Management Bus (SMBus) Mode

The SMBus interface can also be used to control the device. If MODE_SEL = Low (1 k Ω to VSS), Pins 13 and 29 are configured as SDA and SCL. Pins 11 and 28 are address straps ADDR0 and ADDR1 during power up. The maximum operating speed supported on the SMBUS pins is 400 kHz.

表 8-12. SMBus Device Target Addresses⁽¹⁾

ADDR0 (LEVEL)	ADDR1 (LEVEL)	7-BIT TARGET ADDRESS [HEX]	8-BIT WRITE COMMAND [HEX]
L	L	2D	5A
L	R	2E	5C
L	F	2F	5E
L	H	30	60
R	L	31	62
R	R	32	64
R	F	33	66
R	H	34	68
F	L	35	6A
F	R	36	6C
F	F	37	6E
F	H	38	70
H	L	39	72
H	R	3A	74

表 8-12. SMBus Device Target Addresses⁽¹⁾ (continued)

ADDR0 (LEVEL)	ADDR1 (LEVEL)	7-BIT TARGET ADDRESS [HEX]	8-BIT WRITE COMMAND [HEX]
H	F	3B	76
H	H	3C	78

- (1) The 8-bit write command consists of the 7-bit target address (Bits 7:1) with 0 appended to the LSB to indicate an SMBus write. For example, if the 7-bit target address is 0x2D (010 1101'b), the 8-bit write command is 0x5A (0101 1010'b).

8.4.1.1.2 SMBus Read Operation Format

SMBus read operation consists of four parts, as illustrated in [图 8-7](#):

1. The controller begins with a start condition, followed by the target device address with the R/ \bar{W} bit set to 0'b.
2. After an ACK from the target device, the 8-bit register word address is written.
3. After an ACK from the target device, the controller initiates a restart condition, followed by the Target address with the R/ \bar{W} bit set to 1'b.
4. After an ACK from the target device, the 8-bit data is read-back. The last ACK is high if there are no more bytes to read, and the last read is followed by a stop condition.

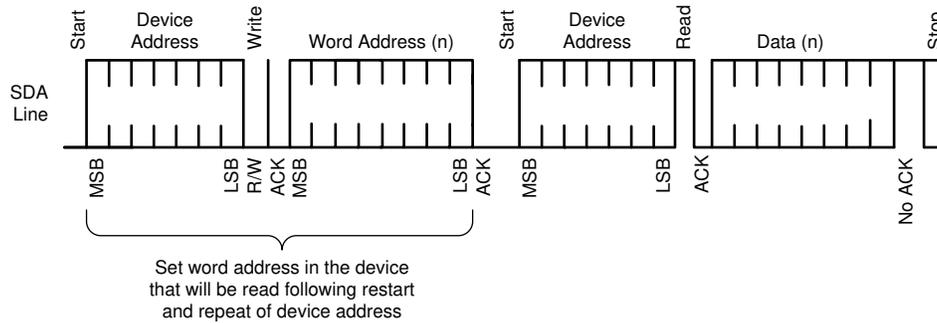


图 8-7. SMBus Read Operation

8.4.2 Serial Peripheral Interface (SPI) Mode

If MODE_SEL = F or H, the LMH1297 is in SPI mode. In SPI mode, the following pins are used for SPI bus communication:

- MOSI (Pin 13): Controller Output Target Input
- MISO (Pin 28): Controller Input Target Output
- SS_N (Pin 11): Target Select (Active Low)
- SCK (Pin 29): Serial Clock (Input to the LMH1297 target device)

8.4.2.1 SPI Read and Write Transactions

Each SPI transaction to a single device is 17 bits long and is framed by SS_N when asserted low. The MOSI input is ignored, and the MISO output is floated whenever SS_N is deasserted (high).

The bits are shifted in left-to-right. The first bit is R/ \bar{W} , which is 1'b for *read* and 0'b for *write*. Bits A7-A0 are the 8-bit register address, and bits D7-D0 are the 8-bit read or write data. The previous SPI command, address, and data are shifted out on MISO as the current command, address, and data are shifted in on MOSI. In all SPI transactions, the MISO output signal is enabled asynchronously when SS_N asserts low. The contents of a single MOSI or MISO transaction frame are shown in [图 8-8](#).

图 8-8. 17-Bit Single SPI Transaction Frame

R/W	A7	A6	A5	A4	A3	A2	A1	A0	D7	D6	D5	D4	D3	D2	D1	D0
-----	----	----	----	----	----	----	----	----	----	----	----	----	----	----	----	----

8.4.2.2 SPI Write Transaction Format

For SPI writes, the R/W bit is 0'b. SPI write transactions are 17 bits per device, and the command is executed on the rising edge of SS_N. The SPI transaction always starts on the rising edge of the clock.

The signal timing for a SPI Write transaction is shown in 图 7-2. The *prime* values on MISO (for example, A7') reflect the contents of the shift register from the previous SPI transaction and are do not care for the current transaction.

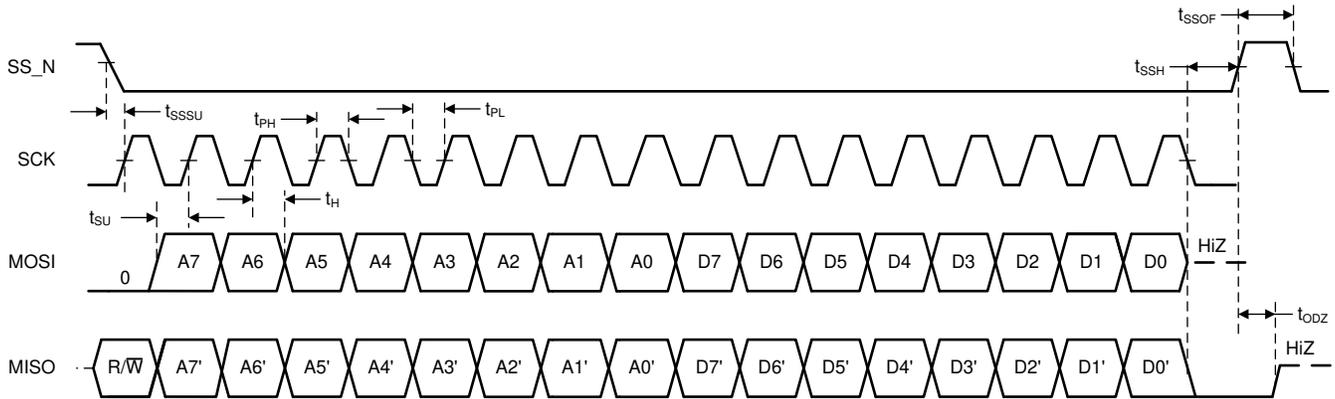


图 8-9. Signal Timing for a SPI Write Transaction

8.4.2.3 SPI Read Transaction Format

A SPI read transaction is 34 bits per device and consists of two 17-bit frames. The first 17-bit read transaction frame shifts in the address to be read, followed by a dummy transaction second frame to shift out 17-bit read data. The R/W bit is 1'b for the read transaction, as shown in 图 7-3.

The first 17 bits from the read transaction specifies 1-bit of R/W and 8-bits of address A7-A0 in the first 8 bits. The eight 1's following the address are ignored. The second dummy transaction acts like a read operation on address 0xFF and needs to be ignored. However, the transaction is necessary to shift out the read data D7-D0 in the last 8 bits of the MISO output. As with the SPI Write, the *prime* values on MISO during the first 16 clocks are listed as do not care for this portion of the transaction. The values shifted out on MISO during the last 17 clocks reflect the read address and 8-bit read data for the current transaction.

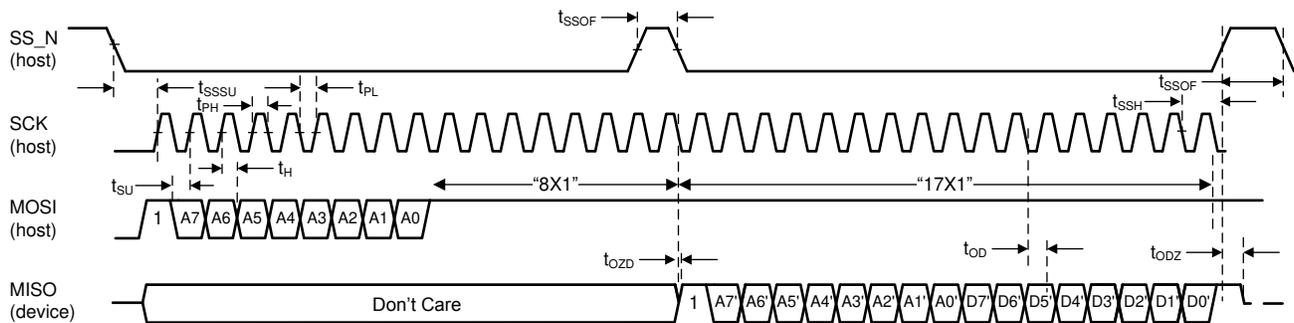


图 8-10. Signal Timing for a SPI Read Transaction

8.4.2.4 SPI Daisy Chain

The LMH1297 supports SPI daisy-chaining among multiple devices, as shown in [图 8-11](#).

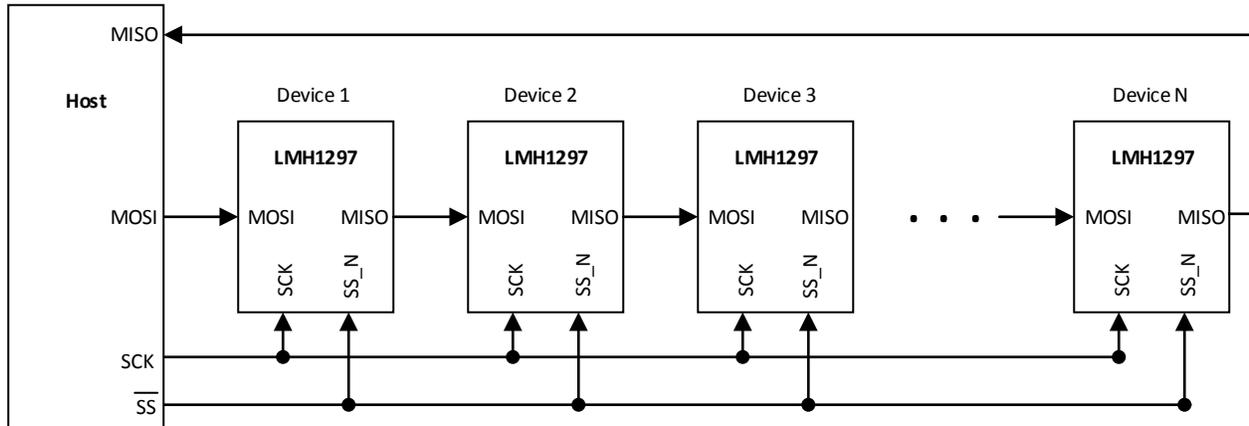


图 8-11. Daisy-Chain Configuration

Each LMH1297 device is directly connected to the SCK and SS_N pins of the host. The first LMH1297 device in the chain is connected to the host's MOSI pin, and the last device in the chain is connected to the host's MISO pin. The MOSI pin of each intermediate LMH1297 device in the chain is connected to the MISO pin of the previous LMH1297 device, thereby creating a serial shift register. In a daisy-chain configuration of $N \times$ LMH1297 devices, the host conceptually sees a shift register of length $17 \times N$ for a basic SPI transaction, during which SS_N is asserted low for $17 \times N$ clock cycles.

8.5 Register Maps

The LMH1297 register map is divided into three register pages. These register pages are used to control different aspects of the LMH1297 functionality. A brief summary of the pages is shown below:

1. **Share Register Page:** this page corresponds to global parameters, such as LMH1297 device ID, I/O direction override, and LOCK_N status configuration. This is the default page at start-up. Access this page by setting Reg 0xFF[2:0] = 000' b.
2. **CTLE/CDR Register Page:** this page corresponds to IN0 PCB CTLE, input and output mux settings, CDR settings, and output interrupt overrides. Access this page by setting Reg 0xFF[2:0] = 100' b.
3. **ConfigIO Register Page:** this page corresponds to SDI_IO Cable Equalizer settings. This page also controls the OUT0, SDI_IO, and SDI_OUT driver output settings. Access this page by setting Reg 0xFF[2:0] = 101' b.

For the complete register map, typical device configurations, and proper register reset sequencing, refer to the [LMH1297 Programming Guide](#).

9 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

9.1 Application Information

9.1.1 SMPTE Requirements and Specifications

SMPTE specifies several key requirements for the Serial Digital Interface to transport digital video over coaxial cables. Such requirements include return loss, AC coupling, and data rate dependency with rise and fall times.

1. **Return Loss:** this specification details how closely the port resembles 75- Ω impedance across a specified frequency band. The LMH1297 features a built-in 75- Ω return-loss network on SDI_IO and SDI_OUT to minimize parasitics and improve overall signal integrity.
2. **AC Coupling:** AC-coupling capacitors are required for transporting uncompressed serial data streams with heavy low-frequency content. The use of 4.7- μ F, AC-coupling capacitors is recommended to avoid low-frequency DC wander.
3. **Rise/Fall Time:** output 75- Ω signals are required to meet certain rise and fall timing depending on the data rate. This improves the eye opening observed for the receiving device. The LMH1297 SDI_IO (in CD mode) and SDI_OUT cable drivers feature automatic edge rate adjustment to meet SMPTE rise and fall time requirements.

TI recommends placing the LMH1297 as close as possible to the 75- Ω BNC ports to meet SMPTE specifications.

9.1.2 Low-Power Optimization in CD Mode

In CD mode, the LMH1297 IN0 CTLE operates in either AM1 Adaptive mode or AM0 Manual mode. When operating in AM1, the LMH1297 uses HEO/VEO Lock Monitoring as a key parameter to achieve lock. HEO/VEO Lock Monitoring determines the CTLE boost setting that produces the best horizontal and vertical eye opening after the CTLE. Once AM1 adaptation is complete and the LMH1297 asserts CDR lock at the optimal IN0 CTLE setting, HEO/VEO Lock Monitoring is no longer required to maintain lock. Therefore, HEO/VEO Lock Monitoring can be disabled by setting CTLE/CDR Reg 0x3E[7] = 0'b **after** lock is declared. Disabling HEO/VEO Lock Monitoring optimizes power dissipation in CD mode, reducing the overall power by approximately 25 mW.

When operating in AM0, the LMH1297 does not use HEO/VEO Lock Monitoring, because the IN0 CTLE setting is set manually by the user. In AM0, HEO/VEO Lock Monitoring can be disabled at any time.

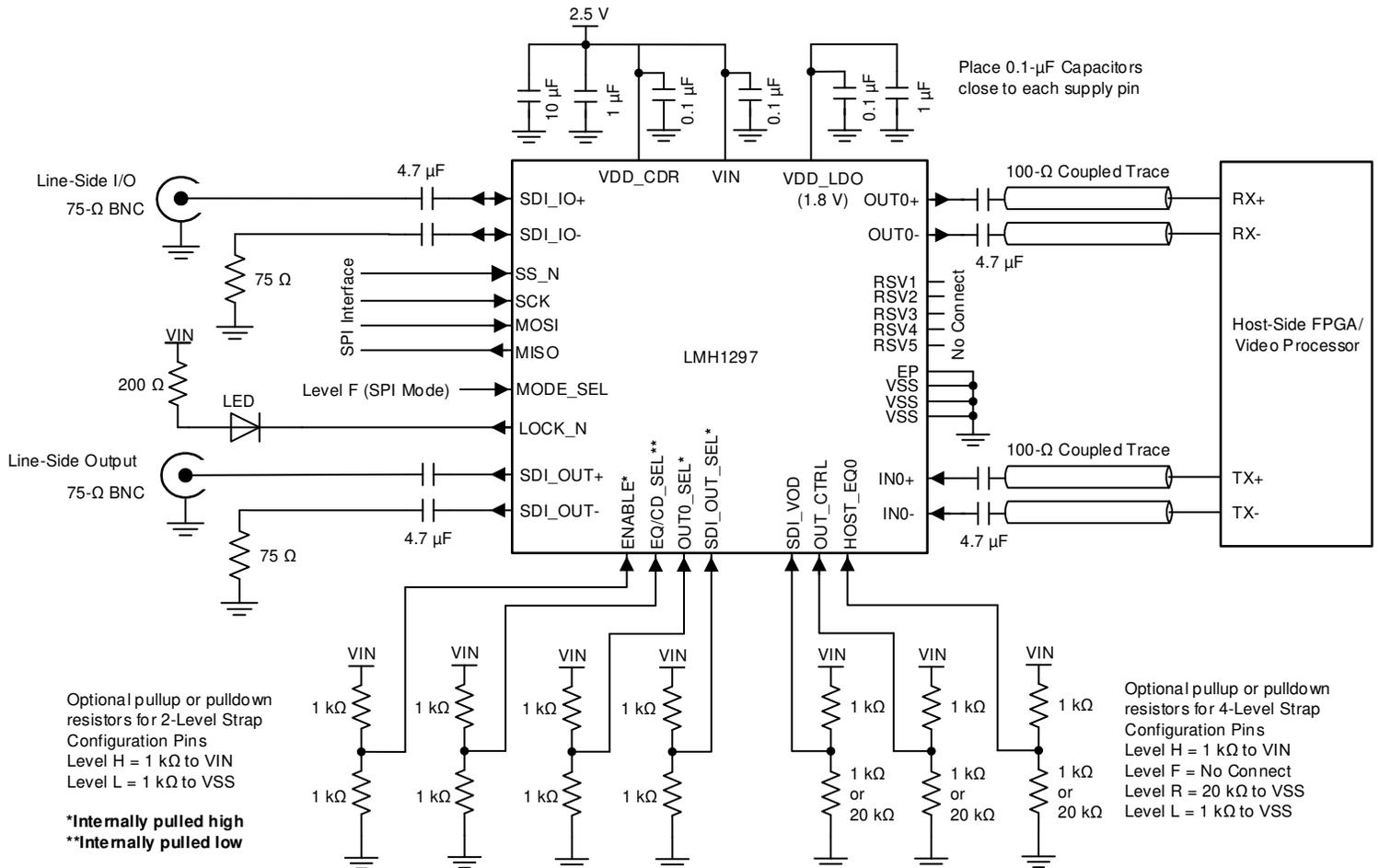
9.1.3 Optimized Loop Bandwidth Settings for Arria 10 FPGA Applications

The LMH1297 default loop bandwidth setting is optimized for a wide variety of applications. For applications using the Intel Arria 10 FPGA, further optimization of the loop bandwidth in CD mode may be required. Refer to the [LMH1297 Programming Guide](#) for detailed register settings when using the LMH1297 in CD mode with the Arria 10 FPGA.

9.2 Typical Applications

The LMH1297 is a bidirectional I/O with integrated reclocker that supports SDI data rates up to 11.88 Gbps. This device supports multiple configurations and can be programmed as a cable equalizer or cable driver. [Figure 9-1](#) shows a typical application circuit for the LMH1297.

Specific examples of typical applications for the LMH1297 as a bidirectional I/O and cable equalizer with loop-through are detailed in the following subsections.



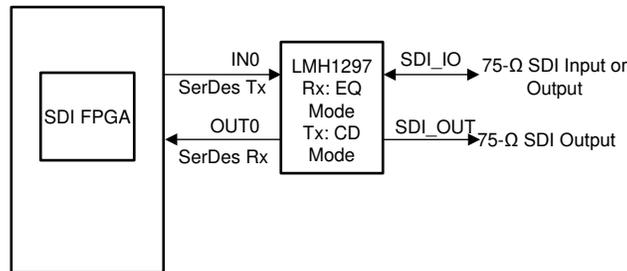
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Figure 9-1. LMH1297 Typical Application Circuit

9.2.1 Bidirectional I/O

The LMH1297 can be configured as a bidirectional I/O to improve BNC port function flexibility. In EQ mode, the LMH1297 equalizes 75-Ω SDI input data at SDI_IO and outputs from OUT0 to an FPGA Rx. SDI_OUT is used as an optional loop-through SDI output. In CD mode, the LMH1297 equalizes 100-Ω SDI input data at IN0 and uses the dual cable drivers at SDI_IO and SDI_OUT to drive out the SDI signal. OUT0 can be used as a loop-back output for system monitoring.

图 9-2 shows a typical application where an LMH1297 is used alongside an SDI FPGA to enable bidirectional I/O port functionality.



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图 9-2. LMH1297 Bidirectional I/O Application

9.2.1.1 Design Requirements

For general LMH1297 design requirements, reference the guidelines in 表 9-1.

For bidirectional I/O application-specific requirements, reference the guidelines in 表 9-2.

表 9-1. LMH1297 General Design Requirements

DESIGN PARAMETER	REQUIREMENTS
SDI_IO+, SDI_OUT+ AC-coupling capacitors	4.7- μ F capacitors recommended
SDI_IO -, SDI_OUT - AC-coupling capacitors	4.7- μ F capacitors recommended, AC terminated with 75 Ω to VSS.
IN0± and OUT0± AC-coupling capacitors	4.7- μ F capacitors recommended
Input and Output Terminations	Input and output terminations provided internally. Do not add external terminations.
DC power supply decoupling capacitors	10- μ F and 1- μ F bulk capacitors; place close to each device. 0.1- μ F capacitor; place close to each supply pin.
VDD_LDO decoupling capacitors	1- μ F and 0.1- μ F capacitors; place as close as possible to the device VDD_LDO pin.
MODE_SEL Pin	SPI: Leave MODE_SEL unconnected (Level F) SMBus: Connect 1 kΩ to VSS (Level L)
Input Reclocked Data Rate (SDI_IO in EQ mode or IN0 in CD mode)	11.88 Gbps, 5.94 Gbps, 2.97 Gbps, 1.485 Gbps, or Divide-by-1.001 sub-rates and 270 Mbps. For all other input data rates, the reclocker is automatically bypassed.

表 9-2. LMH1297 Bidirectional I/O Requirements

DESIGN PARAMETER	REQUIREMENTS
EQ/CD_SEL Pin	1 kΩ to VSS (Level L) when SDI_IO is used as a cable EQ input 1 kΩ to VIN (Level H) when SDI_IO is used as a cable driver output
OUT0_SEL Pin	1 kΩ to VSS (Level L) to enable OUT0 for monitoring purposes 1 kΩ to VIN (Level H) to disable OUT0 (available only in CD mode)
SDI_OUT_SEL Pin	1 kΩ to VSS (Level L) to enable cable loop-through (EQ mode) or secondary cable output (CD mode) 1 kΩ to VIN (Level H) to disable cable loop-through (EQ mode) or secondary cable output (CD mode)

9.2.1.2 Detailed Design Procedure

The design procedure for bidirectional I/O applications is as follows:

1. Select a power supply that meets the DC and AC requirements in [§ 7.3](#).
2. Choose a small 0402 surface mount ceramic capacitor for AC-coupling capacitors to maintain characteristic impedance.
3. Choose a high-quality, 75- Ω BNC connector that is capable of supporting 11.88-Gbps applications. Consult a BNC supplier regarding insertion loss, impedance specifications, and recommended footprint for meeting SMPTE return loss.
4. Follow detailed high-speed layout recommendations provided in [§ 11.1](#) to ensure optimal signal quality when interconnecting 75- Ω and 100- Ω signals to the LMH1297.
5. Determine whether SPI or SMBus communication is necessary. If the LMH1297 must be programmed with settings other than what is offered by pin control, users must use SPI or SMBus mode for additional programming.
6. Configure EQ/CD_SEL, OUT0_SEL, and SDI_OUT_SEL pins according to the desired default use case. In a bidirectional I/O application, the EQ/CD_SEL pin or register settings may be modified to switch between EQ mode and CD mode.
7. Configure the LMH1297 in EQ mode. Tune the HOST_EQ0 100- Ω driver control pin to equalize the PCB output trace following OUT0 \pm . Use register control for more tuning options if necessary.
8. Configure the LMH1297 in CD mode. Tune the SDI_VOD output amplitude control pin for optimal signal quality depending on the cable length attached at SDI_IO+ and SDI_OUT+. Use register control for more tuning options if necessary.

9.2.1.3 Application Curves

Depending on operation in EQ or CD mode, the LMH1297 performance was measured with the test setups shown in [图 9-3](#) and [图 9-4](#).

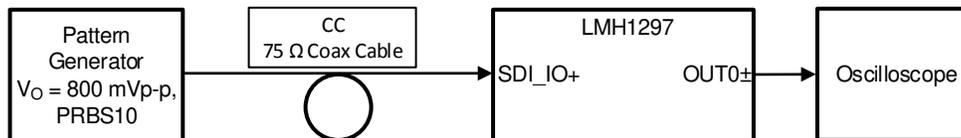


图 9-3. Test Setup for LMH1297 in EQ Mode

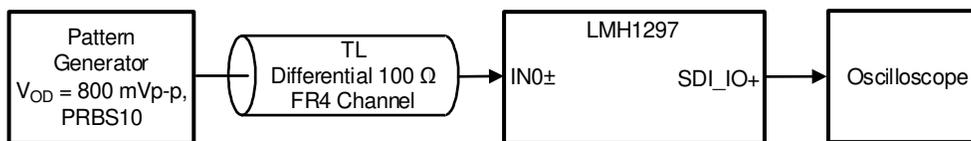
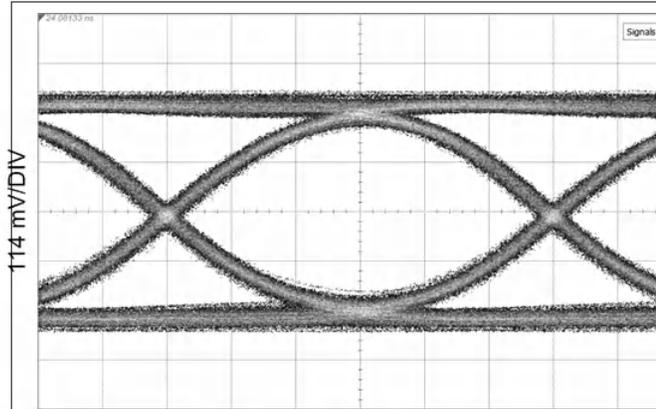


图 9-4. Test Setup for LMH1297 in CD Mode

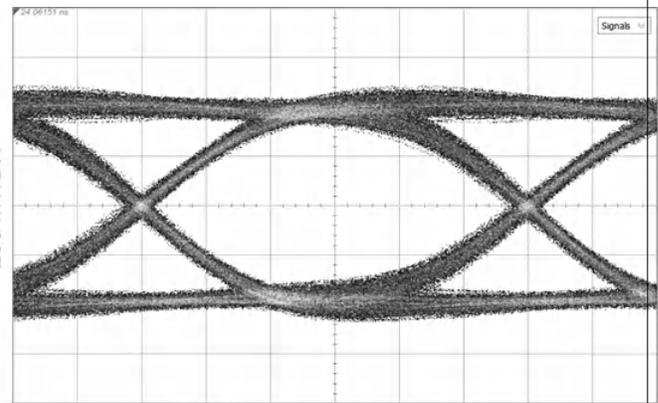
The eye diagrams in this subsection show how the LMH1297 improves overall signal integrity in the data path for 75- Ω coax at SDI_IO+ when operating in EQ mode and 100- Ω differential FR4 PCB trace at IN0 \pm when operating in CD mode.



14 ps/DIV

EQ mode, measured at OUT0± HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

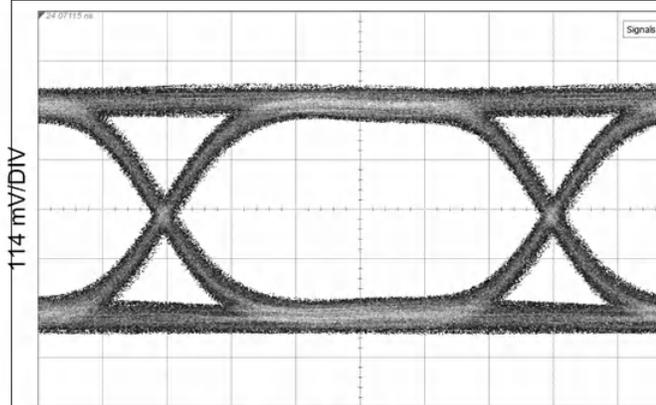
图 9-5. 11.88 Gbps, CC = 75-m Belden 1694A, Rlocked



14 ps/DIV

CD mode, measured at SDI_IO+ HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

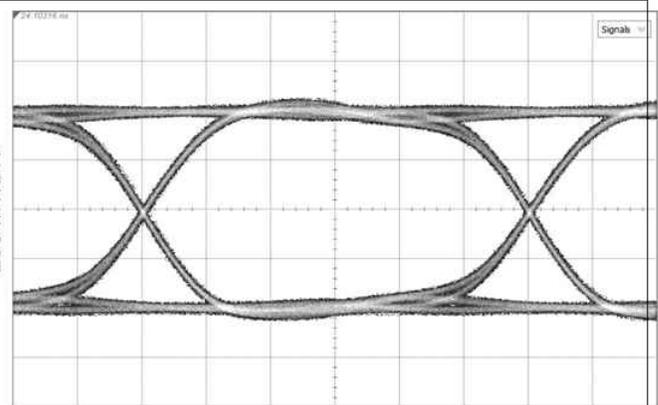
图 9-6. 11.88 Gbps, TL = 20" FR4, Rlocked



28 ps/DIV

EQ mode, measured at OUT0± HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

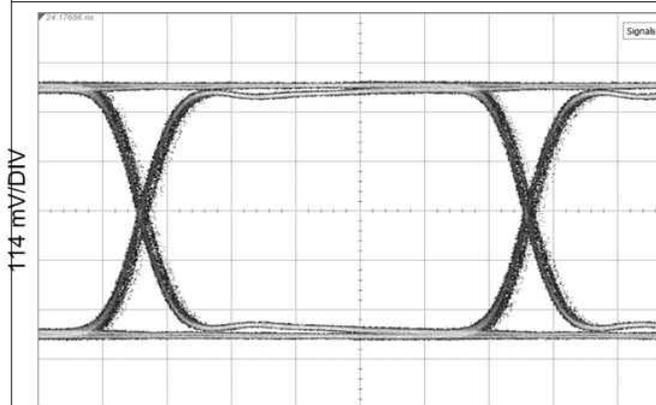
图 9-7. 5.94 Gbps, CC = 120-m Belden 1694A, Rlocked



28 ps/DIV

CD mode, measured at SDI_IO+ HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

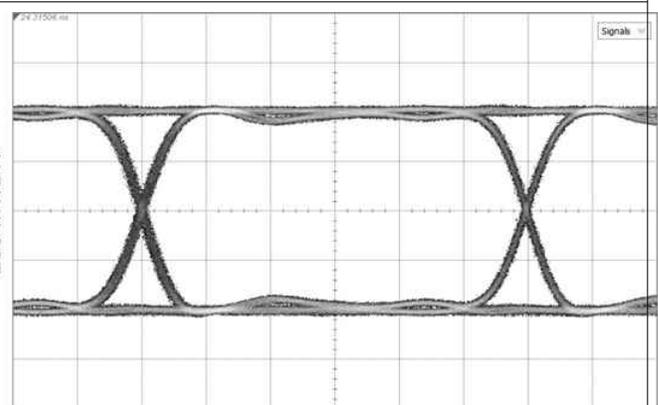
图 9-8. 5.94 Gbps, TL = 20" FR4, Rlocked



56 ps/DIV

EQ mode, measured at OUT0± HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

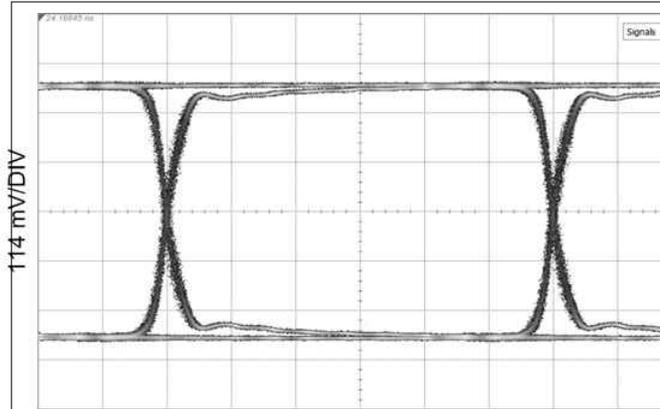
图 9-9. 2.97 Gbps, CC = 200-m Belden 1694A, Rlocked



56 ps/DIV

CD mode, measured at SDI_IO+ HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

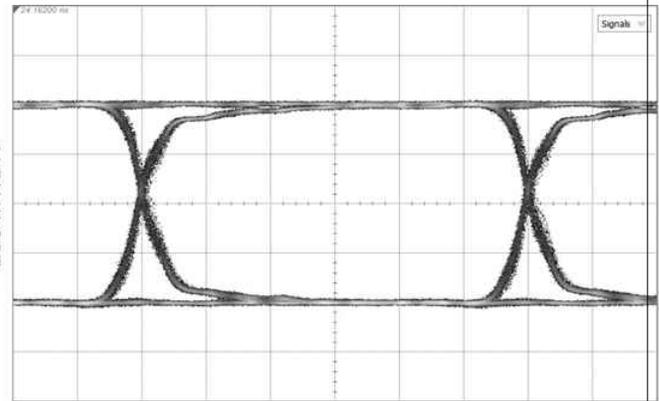
图 9-10. 2.97 Gbps, TL = 20" FR4, Rlocked



112 ps/DIV

EQ mode, measured at OUT0± HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

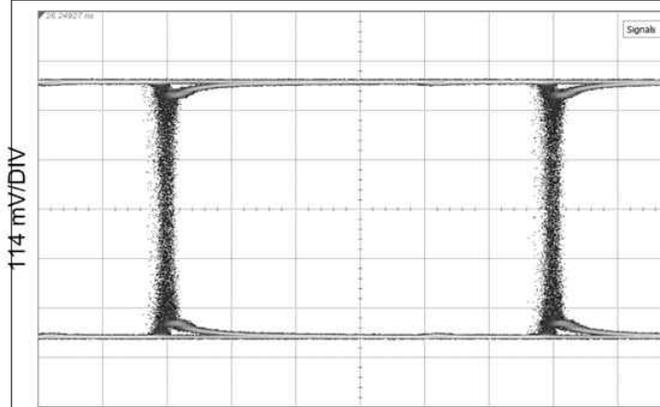
图 9-11. 1.485 Gbps, CC = 300-m Belden 1694A, Reclocked



112 ps/DIV

CD mode, measured at SDI_IO+ HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

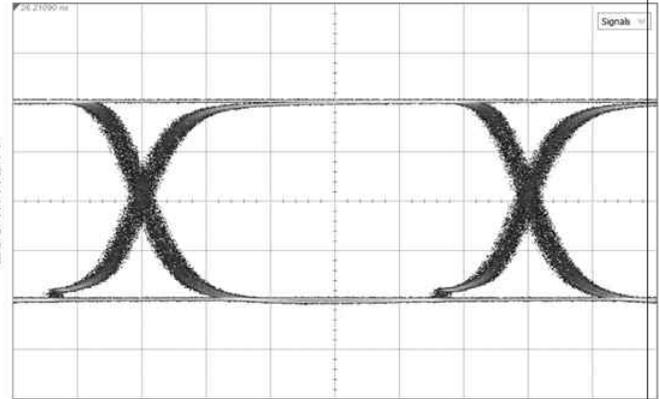
图 9-12. 1.485 Gbps, TL = 20" FR4, Reclocked



617 ps/DIV

EQ mode, measured at OUT0± HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

图 9-13. 270 Mbps, CC = 600-m Belden 1694A, Reclocked



617 ps/DIV

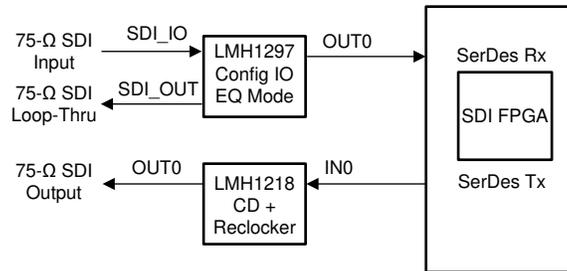
CD mode, measured at SDI_IO+ HOST_EQ0 = F,
SDI_OUT_SEL = H, OUT_CTRL = F

图 9-14. 270 Mbps, TL = 20" FR4, Reclocked

9.2.2 Cable Equalizer With Loop-Through

The LMH1297 can be configured as a cable equalizer with loop-through output. In EQ mode, the LMH1297 takes in SDI data at the SDI_IO adaptive cable equalizer input and outputs the reclocked SDI signal at OUT0. Meanwhile, a redundant reclocked loop-through SDI signal is output on SDI_OUT for system monitoring purposes.

图 9-15 shows a typical application of an LMH1297 as a cable loop-through device. In this example, the LMH1297 provides an SDI input to the SDI FPGA. Concurrently, the equalized and reclocked SDI_IO signal is sent to the loop-through SDI_OUT cable driver output. Meanwhile, the FPGA sends post-processed SDI data out on an LMH1218 cable driver with integrated reclocker.



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图 9-15. LMH1297 Cable Loop-Through Application

9.2.2.1 Design Requirements

See 表 9-1 in *Bidirectional I/O Design Requirements* for general LMH1297 design requirements.

For cable equalizer with loop-through application-specific requirements, reference the guidelines in 表 9-3.

表 9-3. LMH1297 Cable Loop-Through Requirements

DESIGN PARAMETER	REQUIREMENTS
EQ/CD_SEL Pin	1 kΩ to VSS (Level L) to enable SDI_IO as a cable EQ input
OUT0_SEL Pin	1 kΩ to VSS (Level L) to enable OUT0 as PCB output to the FPGA
SDI_OUT_SEL Pin	1 kΩ to VSS (Level L) to enable SDI_OUT as a loop-through output

9.2.2.2 Detailed Design Procedure

See *Bidirectional I/O Detailed Design Procedure* and follow Steps 1-5. Refer to additional steps below for cable equalizer with loop-through applications.

1. Configure EQ/CD_SEL and SDI_OUT_SEL pins according to the desired default use case. In a cable loop-through application, the EQ/CD_SEL pin must be set to Level L so that the LMH1297 operates in EQ mode. Also note that in EQ mode, OUT0 is always enabled, regardless of the logic applied to OUT0_SEL.
2. Tune the HOST_EQ0 100-Ω driver control pin to equalize the PCB output trace following OUT0±. Use register control for more tuning options if necessary.

9.2.2.3 Application Curves

In EQ mode, the LMH1297 SDI_OUT performance was measured with the test setup shown in 图 9-16.

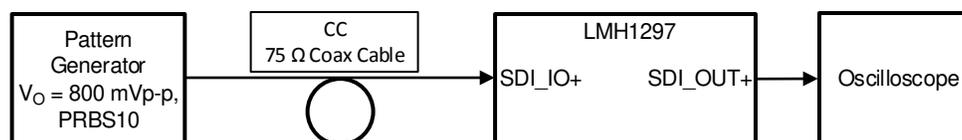
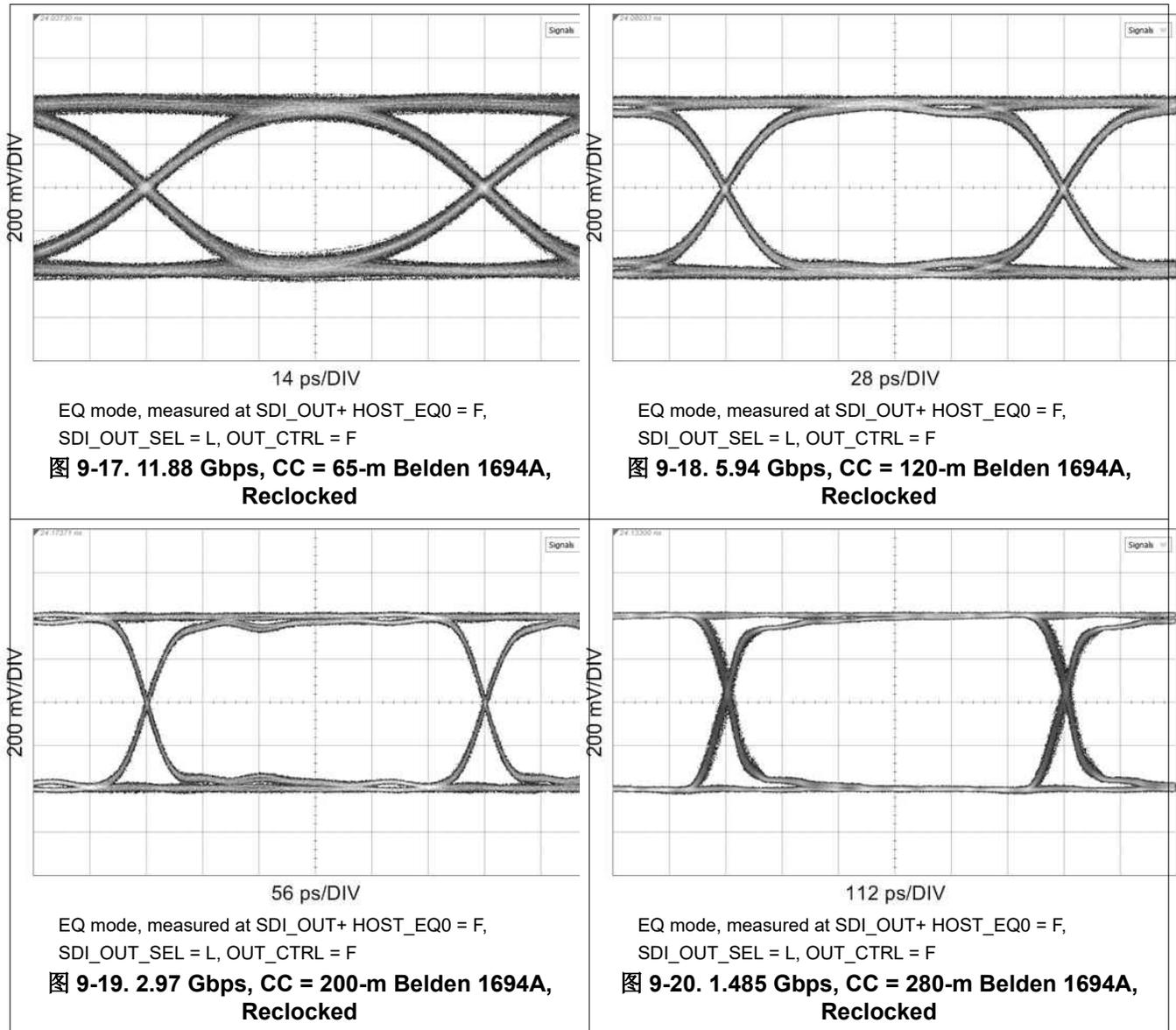
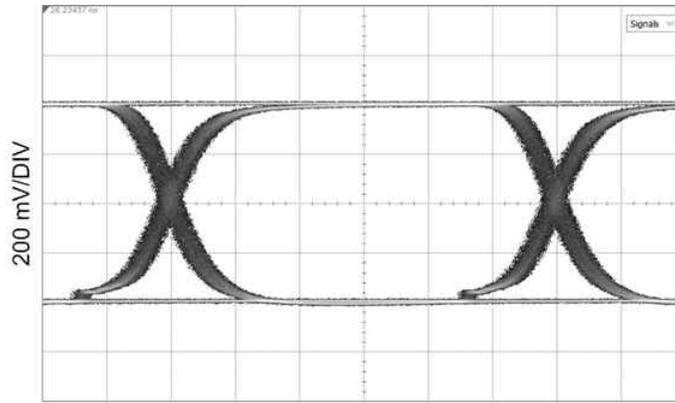


图 9-16. Test Setup for LMH1297 Loop-Through in EQ Mode

The eye diagrams in this subsection show the LMH1297 75-Ω loop-through output at SDI_OUT+.





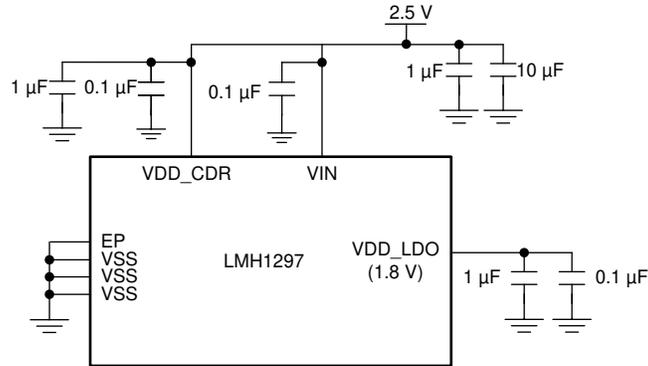
617 ps/DIV

EQ mode, measured at SDI_OUT+ HOST_EQ0 = F, SDI_OUT_SEL = L, OUT_CTRL = F

图 9-21. 270 Mbps, CC = 600-m Belden 1694A, Relocked

10 Power Supply Recommendations

The LMH1297 requires decoupling capacitors to ensure a stable power supply. For power supply decoupling, 0.1- μ F surface-mount ceramic capacitors must be placed close to each VDD_CDR, VDD_LDO, and VIN supply pin to VSS. Larger bulk capacitors (for example, 10 μ F and 1 μ F) are recommended for VDD_CDR and VIN.



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图 10-1. Recommended Power Supply Decoupling

Good supply bypassing requires low inductance capacitors. This can be achieved through an array of multiple small body size surface-mount bypass capacitors to keep low supply impedance. Better results can be achieved through the use of a buried capacitor formed by a VDD and VSS plane separated by 2-4 mil dielectric in a printed-circuit board.

11 Layout

11.1 Layout Guidelines

The following guidelines are recommended to optimize the board layout for the LMH1297.

11.1.1 Board Stack-Up and Ground References

- Choose a suitable board stack-up that supports 75- Ω single-ended trace and 100- Ω differential trace routing on the top layer of the board. This is typically done with a Layer 2 ground plane reference for the 100- Ω differential traces and a Layer 3 ground plane reference for the 75- Ω single-end traces.
- Maintain a distance of at least 5 times the trace width between signal trace and ground reference if they are on the same layer. This prevents unwanted changes in the characteristic impedance.
- Maintain a consistent ground plane reference for each high-speed trace from source to endpoint. Ground reference discontinuities lead to characteristic impedance mismatch.

11.1.2 High-Speed PCB Trace Routing and Coupling

Observe the following general high-speed recommendations for high-speed trace routing:

- For differential pairs, maintain a uniform width and gap for each differential pair where possible. When traces must diverge (for example, due to AC-coupling capacitors), ensure that the traces branch out or merge uniformly.
- To prevent reflections due to trace routing, ensure that trace bends are at most 45°. Right angle bends should be implemented with at least two 45° corners. Radial bends are ideal.
- Avoid using signal vias. If signal vias must be used, a return path (GND) via must be placed near the signal via to provide a consistent ground reference and minimize impedance discontinuities.
- Avoid via stubs by back-drilling as necessary.

11.1.2.1 SDI_IO \pm and SDI_OUT \pm :

- Use an uncoupled trace with 75- Ω single-ended impedance for signal routing to SDI_IO \pm and SDI_OUT \pm .
- The trace width is typically 8-10 mils with reference to a Layer-3 ground plane.

11.1.2.2 IN0 \pm and OUT0 \pm :

- Use coupled traces with 100- Ω differential impedance for signal routing to IN0 \pm and OUT0 \pm .
- The trace width is typically 5-8 mils with reference to a Layer-2 ground plane.

11.1.3 Anti-Pads

- Place anti-pads (ground relief) on the power and ground planes directly under the 4.7- μ F, AC-coupling capacitor and IC landing pads to minimize parasitic capacitance. The size of the anti-pad and the number of layers to use the anti-pad depend on the board stack-up and can be determined by a 3-dimension electromagnetic simulation tool.

11.1.4 BNC Connector Layout and Routing

- Use a well-designed BNC footprint to ensure the BNC's signal landing pad achieves 75- Ω characteristic impedance. BNC suppliers usually provide recommendations on BNC footprint for best results.
- Keep trace length short between the BNC and SDI_IO \pm . The trace routing for SDI_IO+ and SDI_IO- should be as symmetrical as possible, with approximately equal lengths and equal loading. The same is true for SDI_OUT+ and SDI_OUT-.

11.1.5 Power Supply and Ground Connections

- Connect each supply pin (VDD_CDR, VIN, VDD_LDO) directly to the power or ground planes with a short via. The via is usually placed tangent to the supply pins' landing pads with the shortest trace possible.
- Power supply decoupling capacitors should be a small physical size (0402 or smaller) and placed close to the supply pins to minimize inductance. The capacitors are commonly placed on the bottom layer and share the ground of the EP (Exposed Pad).

11.1.6 Footprint Recommendations

- Stencil parameters for the EP (Exposed Pad) such as aperture area ratio and the fabrication process have a significant impact on paste deposition. Inspection of the stencil prior to placement of the QFN package is highly recommended to improve board assembly yields. If the via and aperture openings are not carefully monitored, the solder may flow unevenly through the EP. Stencil parameters for aperture opening and via locations are shown in the RTV package drawing in [# 13](#).
- The EP of the package must be connected to the ground plane through a 3 × 3 via array. These vias are solder-masked to avoid solder flowing into the plated-through holes during the board manufacturing process. Details about via dimensions are also shown in the RTV package drawing in [# 13](#).

More information on the QFN style package is provided in [QFN/SON PCB Attachment Application Report](#).

11.2 Layout Example

The example shown in [图 11-1](#) demonstrates the LMH1297 layout guidelines highlighted in [# 11.1](#).

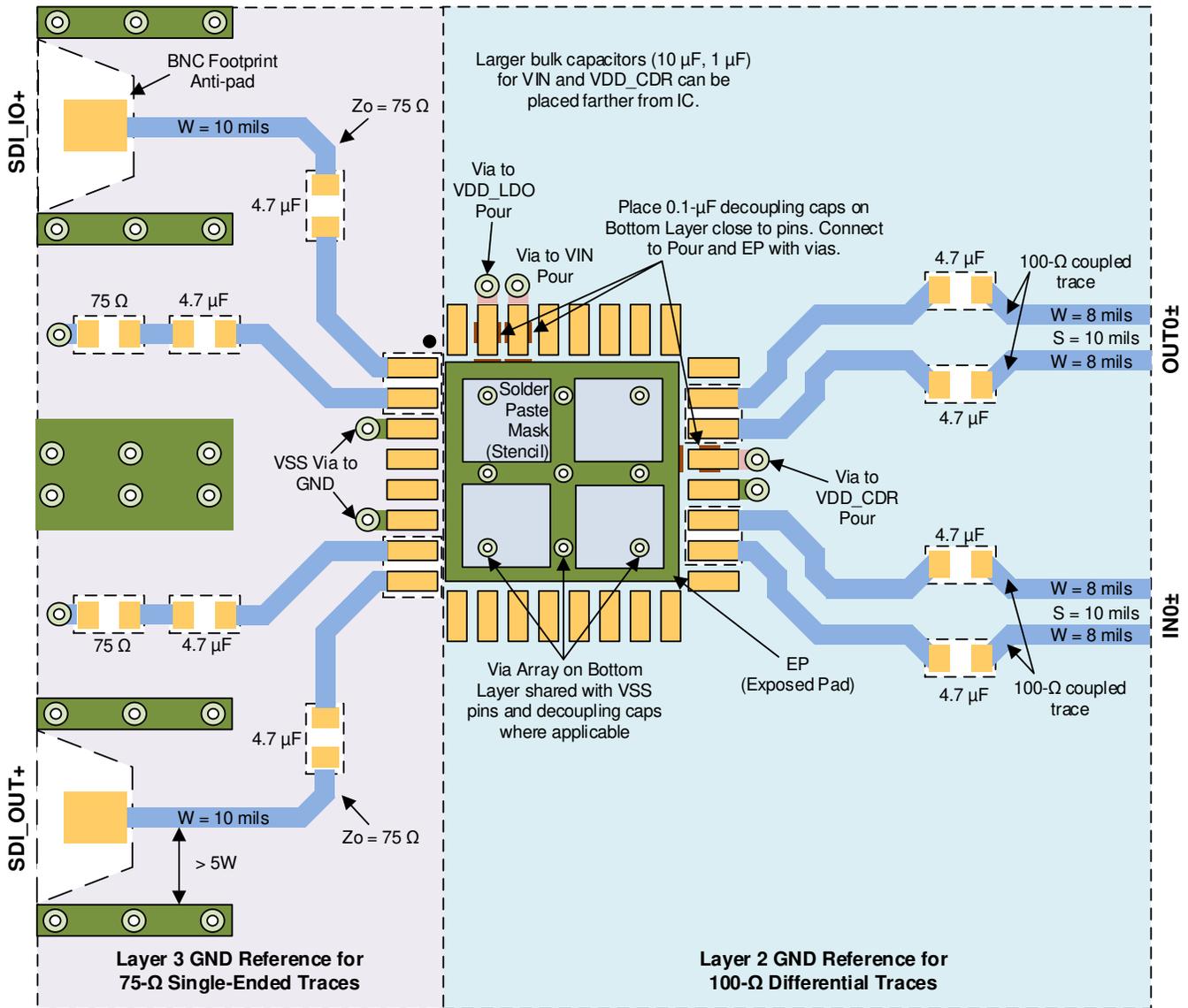


图 11-1. LMH1297 High-Speed Trace Layout Example

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Absolute Maximum Ratings for Soldering](#)
- Texas Instruments, [LMH1297 Programming Guide](#)
- Texas Instruments, [QFN/SON PCB Attachment Application Report](#)

12.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.3 支持资源

TI E2E™ [支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMH1297RTVR	ACTIVE	WQFN	RTV	32	1000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	L1297	Samples
LMH1297RTVT	ACTIVE	WQFN	RTV	32	250	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	L1297	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

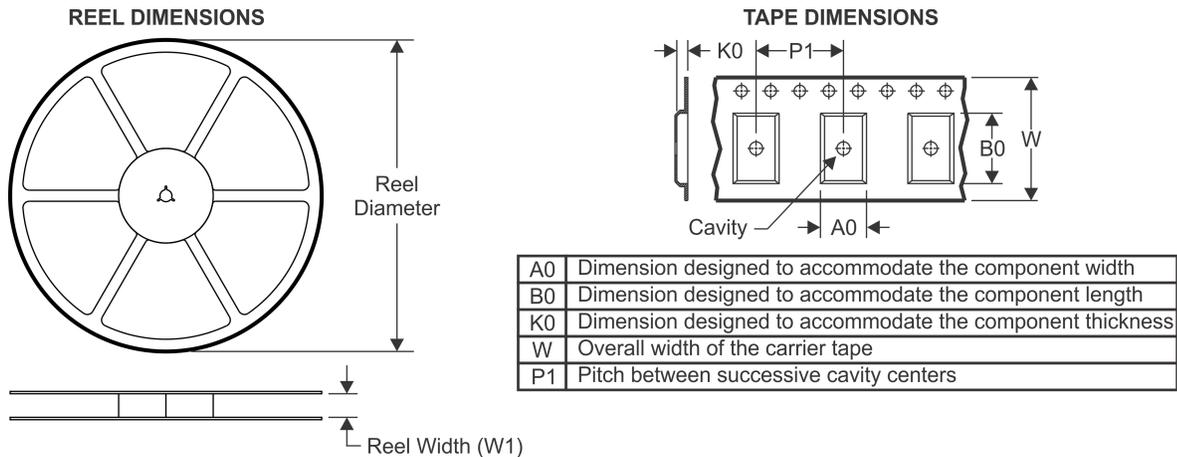
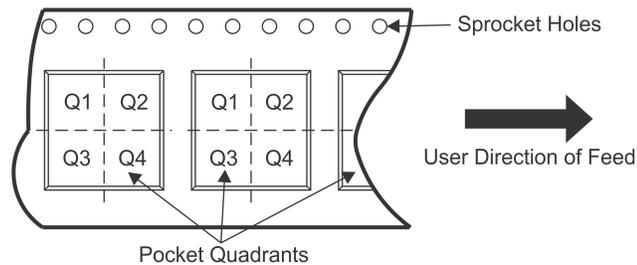
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

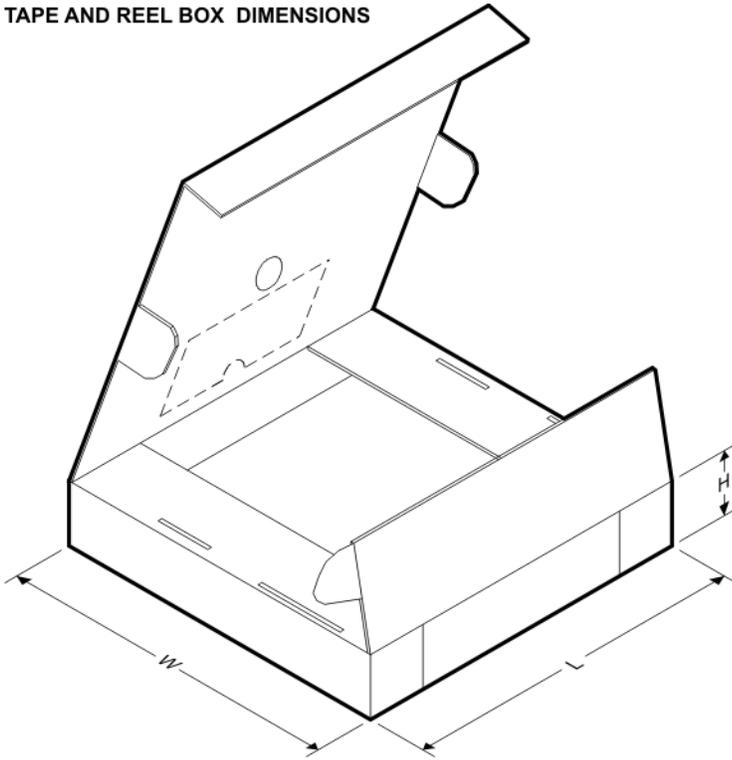
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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

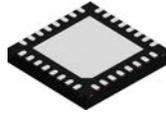
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH1297RTVR	WQFN	RTV	32	1000	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
LMH1297RTVT	WQFN	RTV	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH1297RTVR	WQFN	RTV	32	1000	210.0	185.0	35.0
LMH1297RTVT	WQFN	RTV	32	250	210.0	185.0	35.0

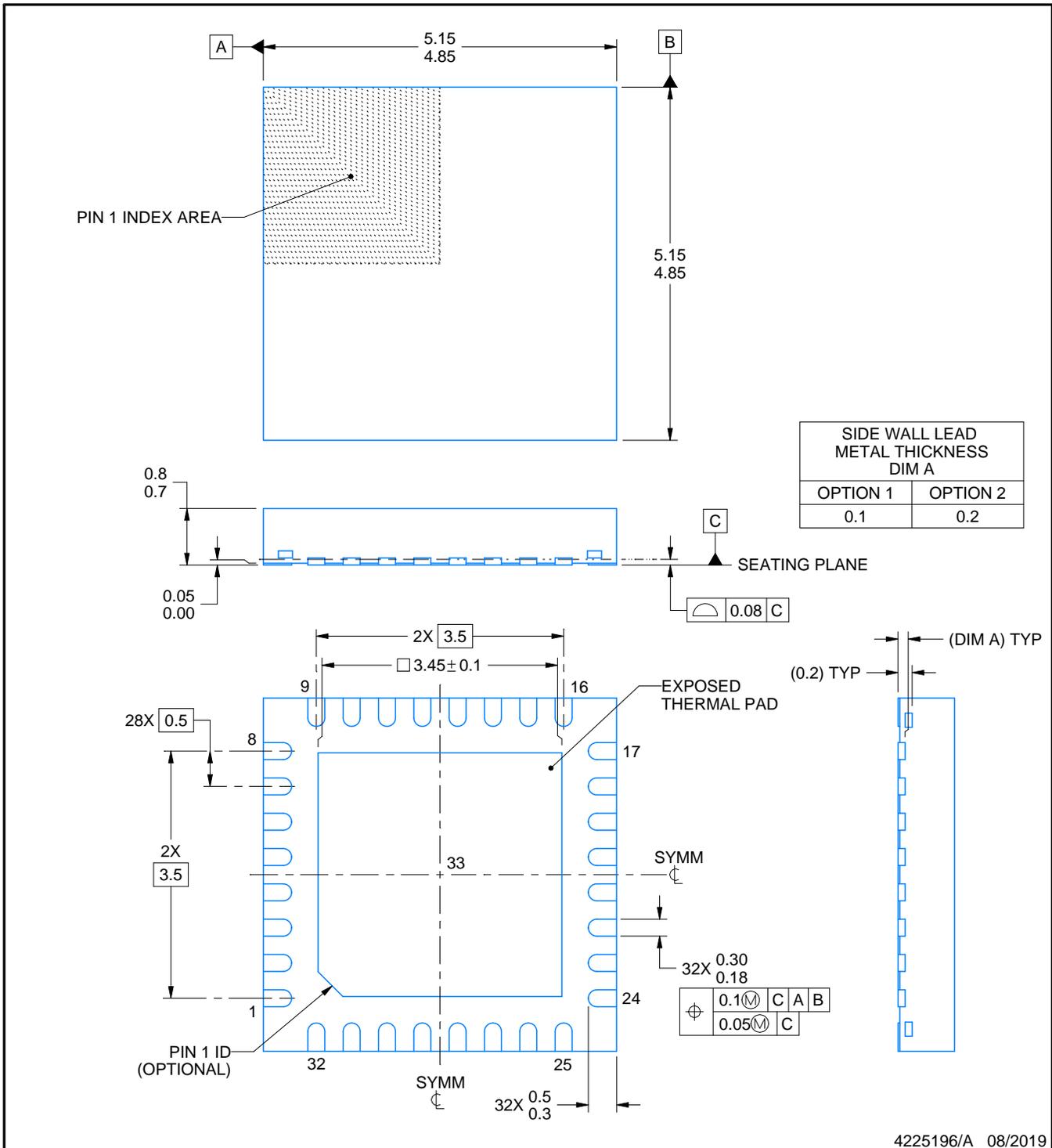
RTV0032E



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4225196/A 08/2019

NOTES:

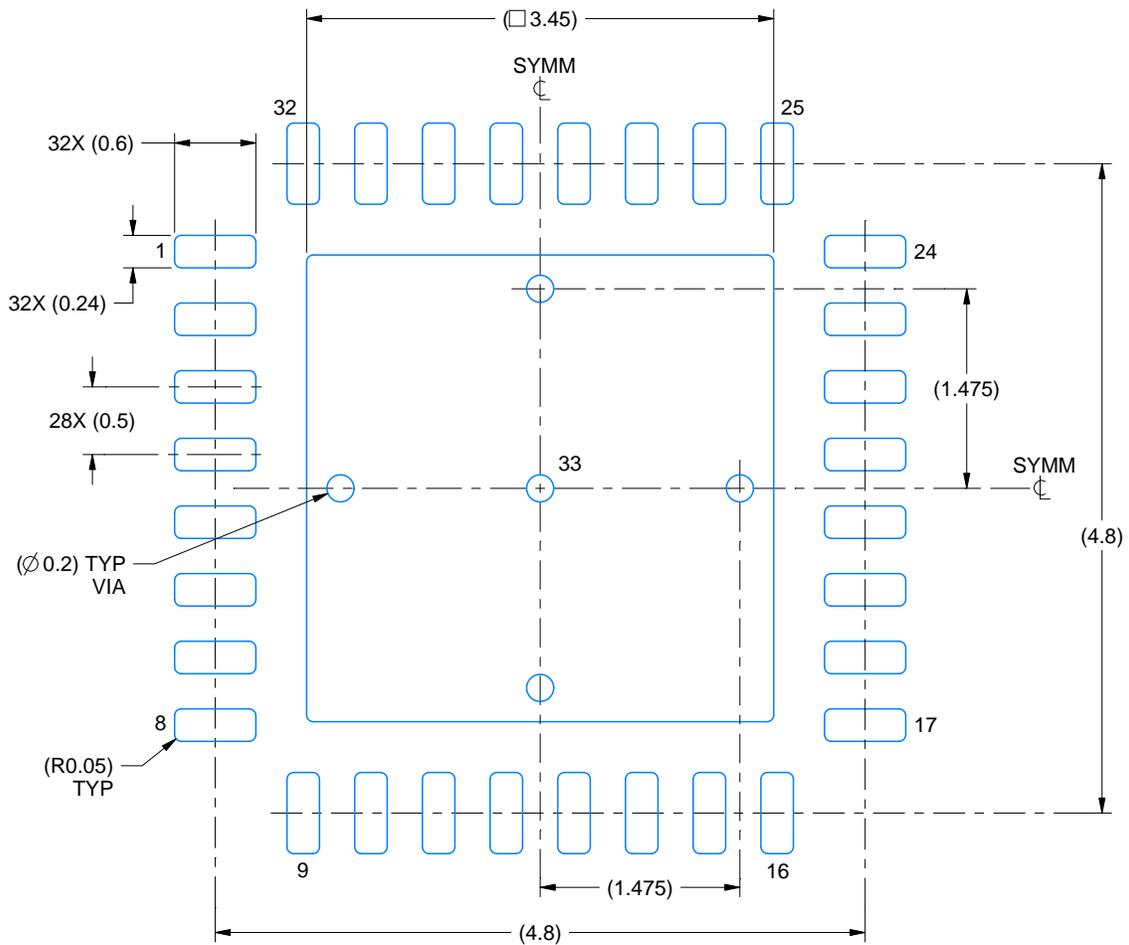
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

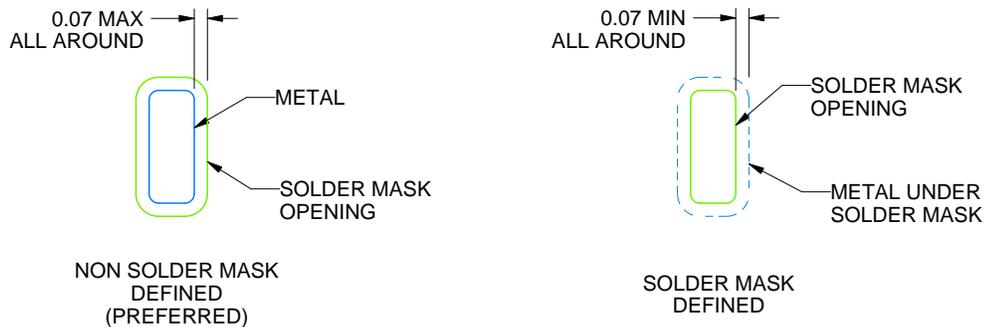
RTV0032E

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:18X



SOLDER MASK DETAILS

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NOTES: (continued)

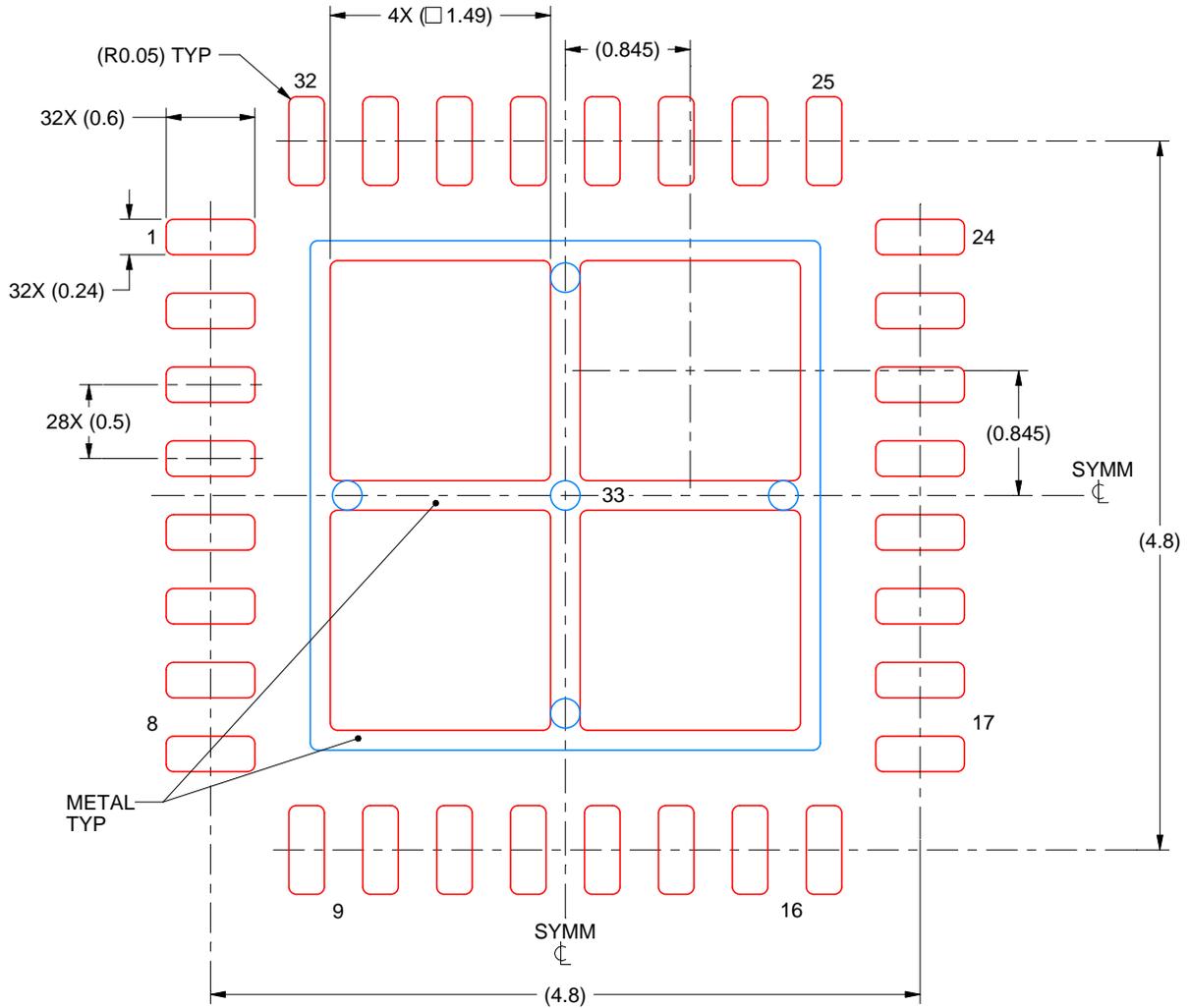
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RTV0032E

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 33:
 75% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
 SCALE:20X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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